DESCRIPTION

This document describes the specification for the F1300 **D**igital **P**re-**D**istortion Demodulator for PA linearization. This device is one of 2 variants to cover common UTRA bands. See the Part# Matrix below for details.

COMPETITIVE ADVANTAGE

In typical basestation transmitters a digital pre-distortion loop is employed to improve the Transmitter performance. The signal coming out of the PA is sampled so that the I&Q data at Baseband can be pre-distorted before being sent to the Tx DAC to counteract the distortion inherent in the downstream PA. The signal coupled from the PA is adjusted via a digital step attenuator to a lower level and then sub-sampled at an IF frequency of ~200 MHz which necessitates the need for a highly linear demodulator to downmix to quadrature IF from the Transmit frequency. By sampling IF_I and IF_Q independently and then digitally combining these signals, an effective doubling of the sample rate can be achieved. Any distortion in this path will degrade the performance of the DPD algorithm. By utilizing an ultra-linear demodulator w/integrated DSA such as the F1300, the ACLR and/or power consumption of the full Tx system can be improved significantly.

- ✓ DPD full path ACLR: ⇓ **1 dB**
- ✓ Icc: DPD function Power Consumption ⇓ **40%**
- ✓ Zero-Distortion™ Demod eliminates 2 IF amps
- ✓ Integrates 2 BPFs, 2 Baluns, 2 SP2Ts
- ✓ Glitch-Free™ gain control

Zero-Distortion™

Glitch-Free™

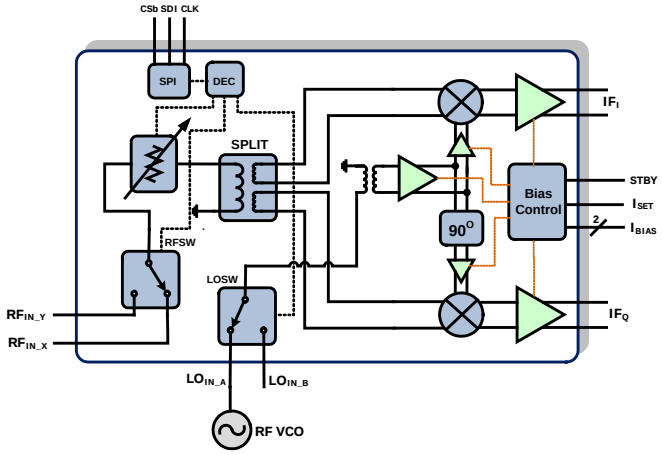
PART# MATRIX

Part#	RF range	UTRA bands	IF freq range	Typ. Gain	Injection
F1300	550 - 1150	5,6,8,12,13, 14,17	20 - 350	12.5	High Side or Low Side
F1350	1300 - 2900	1,2,3,4,9,10 7,21, 24, 38	20 - 500	12.5	High Side or Low Side

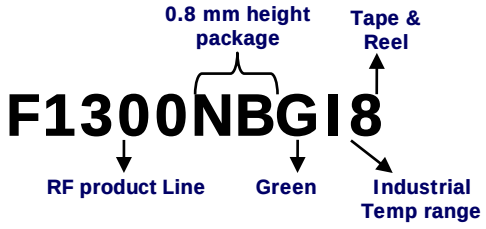
FEATURES (I OR Q PATH)

- Wide flat performance IF BW
- Wide RF and LO BWs (~ 0.8 GHz)
- Ideal for Multi-Carrier Systems
- Drives ADC directly
- Ultra linear +43 dBm $IP3_O$
- Low Noise Figure
- Excellent ACLR performance
- **200Ω** output impedance
- Fully integrated DPD demodulator
- 6 x 6 mm 36-pin package
- Standby Mode w/Fast Recovery
- I_{CC}: 262 mA

DEVICE BLOCK DIAGRAM



ORDERING INFORMATION



ABSOLUTE MAXIMUM RATINGS

V_{CC} to GND	-0.3V to +5.5V
SW_Latch, DATA, CSb, CLK	0V to 3.6V
STBY	0V to V_{CC}
IF_I+, IF_I-, IF_Q+, IF_Q-	1V to (Vcc + 0.3V)
IF_BiasI, IF_BiasQ to GND	-0.3V to +1.2V
LO_ADJ to GND	2.1V to 4.0V
RF Input Power (Into RFIN_X or RFIN_Y)	**+27 dBm**
Continuous Power Dissipation	2.5W
θ_{JA} (Junction – Ambient)	+40°C/W
θ_{JC} (Junction – Case) The Case is defined as the exposed paddle	+3°C/W
Operating Temperature Range (Case Temperature)	T_C = -40°C to +105°C
Maximum Junction Temperature	150°C
Storage Temperature Range	-65°C to +150°C
Moisture Sensitivity Level	**1**
Lead Temperature (soldering, 10s)	+260°C

Stresses above those listed above may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

F1300 SPECIFICATION

Refer to Typical Application Circuit when operated with V_{CC} = +5.0V, T_{CASE} = 25C, **F_{RF} = 860 MHz**, **F_{LO} = 1060 MHz**, Gain = G_{MAX}, P_{LO} = 0 dBm, T_C= +25°C, STBY = GND, unless otherwise noted. Full Lineup measured through to I or Q path. IF Transformers and RF trace losses de-embedded.

Parameter	Comment	Symbol	Min	Typ	Max	Units
Logic Input High	For STBY, DATA, CSb, CLK, SW_Latch	V_{IH}	***2.3***			V
Logic Input Low	For STBY, DATA, CSb, CLK, SW_Latch	V_{IL}			***0.5***	V
Logic Current	V_H = 2.3V, V_L = 0V	I_{IH}, I_{IL}	***-135***		***+10***	µA
Supply Voltage(s)	All V_{CC} (operating range)	V_{CC}		4.75 to 5.25		V
Temperature Range	Operating Range	T_{CASE}	-40		+105	degC
Supply Current	Total V_{CC}	I_{SUPP}		***262***	***290[1]***	mA
Supply Current	Standby Mode: STBY > V_{IH}	I_{STBY}		***22***	***27***	mA
RF Freq Range	Sets LO freq range	F_{RF}	700		1100	MHz
IF center Freq Range	Sets LO freq range	F_{IF}	100		250	MHz
Oversample Operating Range	▪ Measure Gain at I&Q ▪ Gain setting = G_{MAX} ▪ F_{LO} = 950 MHz, 1080 MHz ▪ Gain Delta < 2.5 dB	F_{RFD}	***550***		***1150***	MHz
Oversample IF Range	▪ Measure Gain at I&Q ▪ Gain setting = G_{MAX} ▪ F_{LO} = 950 MHz, 1080 MHz ▪ Gain Delta < 2.5 dB	F_{IFD}	***20***		***350***	MHz
IF Linearity BW	▪ RF Freq = 860 MHz ▪ IP3O > +39 dBm ▪ From RF_INX to I+,I- & Q+,Q- ▪ Pin = -11 dBm/Tone ▪ Gain setting = G_{MAX}	IF_{LIN}	100		300	MHz
RF Linearity BW	▪ IF Freq = 200 MHz ▪ IP3O > +37.5 dBm ▪ From RF_INX to I+,I- & Q+,Q- ▪ Pin = -11 dBm/Tone ▪ Gain setting = G_{MAX}	RF_{LIN}	700		1100	MHz
LO Freq Range1	With R20 = 2.8K	F_{LOH1}	650		1300	MHz
LO Freq Range2	With R20 = 4.0K	F_{LOH2}	500		650	MHz
LO Power	Operating Range	P_{LO}		-3 to +3		dBm
RF Input Impedance	Single Ended (RL > 10 dB)	Z_{RF}		50		Ω
IF Output Impedance	Differential (RL > 10 dB)	Z_{IF}		200		Ω
LO port Impedance	Single Ended (RL > 10 dB)	Z_{LO}		50		Ω
Gain maximum	▪ From RF_INX to I+,I- & Q+,Q- ▪ Gain setting = G_{MAX} ▪ Pin = -11 dBm	G_{MAX} or $ATTN_{MIN}$	***11***	***12.5***	***14***	dB
Gain minimum	▪ From RF_INX to I+,I ▪ Gain setting = G_{MIN} ▪ Pin = +14 dBm	G_{MIN} or $ATTN_{MAX}$	***-15***	***-13.5***	***-12***	dB

F1300 SPECIFICATION - CONTINUED

Refer to Typical Application Circuit when operated with V_{CC} = +5.0V, T_{CASE} = 25C, , **F_{RF} = 860 MHz**, **F_{LO} = 1060 MHz**, Gain = G_{MAX}, P_{LO} = 0 dBm, T_C= +25°C, STBY = GND, unless otherwise noted. Full Lineup measured through to I or Q path. IF Transformers and RF trace losses de-embedded.

Parameter	Comment	Symbol	Min	Typ	Max	Units
Noise Figure	▪ From RF_INX to I+,I- out ▪ Gain setting = G_{MAX}	NF		18.3		dB
Output IP3 – G_{MAX}	▪ Measured at I+,I- and Q+,Q- ▪ P_{IN} = -11 dBm per tone ▪ 5 MHz Tone Separation ▪ Gain setting = G_{MAX}	$IP3_{MAX}$	***39***	***43***		dBm
Output IP3 – G_{-20}	▪ Measured at I+,I- and Q+,Q- ▪ P_{IN} = +9 dBm per tone ▪ 5 MHz Tone Separation ▪ Gain setting = G_{-20}	$IP3_{-20}$	39[2]	42		dBm
2nd Harmonic	▪ Measured at I+,I- and Q+,Q- ▪ P_{IN} = -11 dBm ▪ F_{RF} = 860, F_{LO} = 970 ▪ Gain setting = G_{MAX}	H2	-70	-76		dBc
Output IP2	▪ Measured at I+,I- and Q+,Q- ▪ P_{IN} = -11 dBm per tone ▪ 5 MHz Tone Separation ▪ Gain setting = G_{MAX}	$IP2_O$	59	65		dBm
Output compression	▪ Measured at I+,I- and Q+,Q- ▪ P_{IN} = +4 dBm ▪ Gain setting = G_{MAX}	C		***0.3***	***1***	dB
Gain Ripple1	▪ Fixed LO = 1020 MHz ▪ RF = 650 to 1000 MHz ▪ IF = 20 to 370 MHz	Ripple1		0.8	1.4	dB
Gain Ripple2	▪ Fixed LO = 1061.5 MHz ▪ RF = 591.5MHz to 1041.5MHz ▪ IF = 20 to 470 MHz	Ripple2		1.1	1.5	dB
Group Delay Distortion	▪ Fixed LO = 1020 MHz ▪ RF = 650 to 1000 MHz ▪ IF = 20 to 350 MHz	GDD		2		nsec
Quadrature Amplitude Balance	▪ From RF_INX to I+,I- & Q+,Q- ▪ Gain setting = G_{MAX} ▪ Pin = -11 dBm	BAL_G	-0.2		0.2	dB
Quadrature Phase Balance	▪ F_{RF} = 860, F_{LO} = 1060 ▪ Measure with 20 GSa/sec scope	BAL_Φ	-3		+3	degrees
Amplitude Balance over environmentals	▪ F_{RF} = 860, F_{LO} = 1060 ▪ Tc = -40C to 100C ▪ LO drive = -3 dBm to +3 dBm ▪ Measure with 20 GSa/sec scope	$BAL_{G\Delta}$	-0.3		+0.3	dB
Quadrature Phase Balance over environmentals	▪ F_{RF} = 860, F_{LO} = 1060 ▪ Tc = -40C to 100C ▪ LO drive = -3 dBm to +3 dBm ▪ Measure with 20 GSa/sec scope	$BAL_{\Phi\Delta}$	-3		+3	degrees
LO to IF leakage		ISO_{LI}		-30	-25	dBm
LO to RF leakage		ISO_{LR}		-40		dBm
RF to IF isolation		ISO_{RI}		-32	-23	dB
Attenuator Range		Range		25.5		dB

F1300 SPECIFICATION - CONTINUED

Refer to Typical Application Circuit when operated with V_{CC} = +5.0V, T_{CASE} = 25C, , **F_{RF} = 860 MHz**, **F_{LO} = 1060 MHz**, Gain = G_{MAX}, P_{LO} = 0 dBm, T_C= +25°C, STBY = GND, unless otherwise noted. Full Lineup measured through to I or Q path. IF Transformers and RF trace losses de-embedded.

Parameter	Comment	Symbol	Min	Typ	Max	Units
Attenuator Glitching	▪ Step from 15.5 to 16 dB ▪ Step from 16 to 15.5 dB ▪ Measure maximum excursion	$ATTN_G$		0.5		dB
Attenuator Step Accuracy		DNL		0.2		dB
Attenuator Abs. Accuracy		INL		***0.2***	***0.5***	dB
Attenuator Resolution		LSB		0.5		dB
Serial Clock Speed	SPI 3 wire bus	**F_{CLOCK}**		***20***	***50***	MHz
Data to Clock Setup	SPI 3 wire bus	**T_S**	3			ns
Data to Clock Hold	SPI 3 wire bus	**T_H**	3			ns
Clock to CS Setup	SPI 3 wire bus	**T_{EN}**	3			ns
Clock Pulse Width	SPI 3 wire bus	**T_W**	5			ns
LO Switch Isolation		**ISO_{LOSW}**		-45	-36	dB
RF Switch Isolation		**ISO_{RFSW}**		-45	-43	dB
RF Switch and attenuator settling times[3]						
EN bit on	• LO_INA: 1050MHz, +3dBm • RF_INX: 850MHz, -10dBm	**EN_{ON}**		100		nsec
EN bit off		**EN_{OFF}**		50		
RF switched X to Y (no Y signal)		**RF_{SWXY}**		130		
RF switched Y to X (no Y signal)		**RF_{SWYX}**		200		
LO switched A to B (no B signal)		**LO_{SWAB}**		40		
LO switched B to A (no B signal)		**LO_{SWBA}**		20		
Attenuator switched 0dB to 25.5dB (max)		**ATT_{SETL}**		300		
Attenuator switched 25.5dB (max) to 0dB				300		
Attenuator switched 15.5dB to 16dB				250		
Attenuator switched 16dB to 15.5dB				300		

SPECIFICATION NOTES:

1 – Items in min/max columns in ***bold italics*** are Guaranteed by Test
2 – All other Items in min/max columns are Guaranteed by Design Characterization
3 – Excludes SPI write time

POWER-ON SEQUENCE

The power-on sequence ensures F1300 works in default mode once powered on. If the F1300 is programmed after applying DC power, the following power-on sequence is not needed.

The power-on sequence should be:

1. CSb & SW_LATCH must be set low at power-on
2. Once powered on, first set SW_LATCH high, then set CSb high
3. Proceed with normal programming.

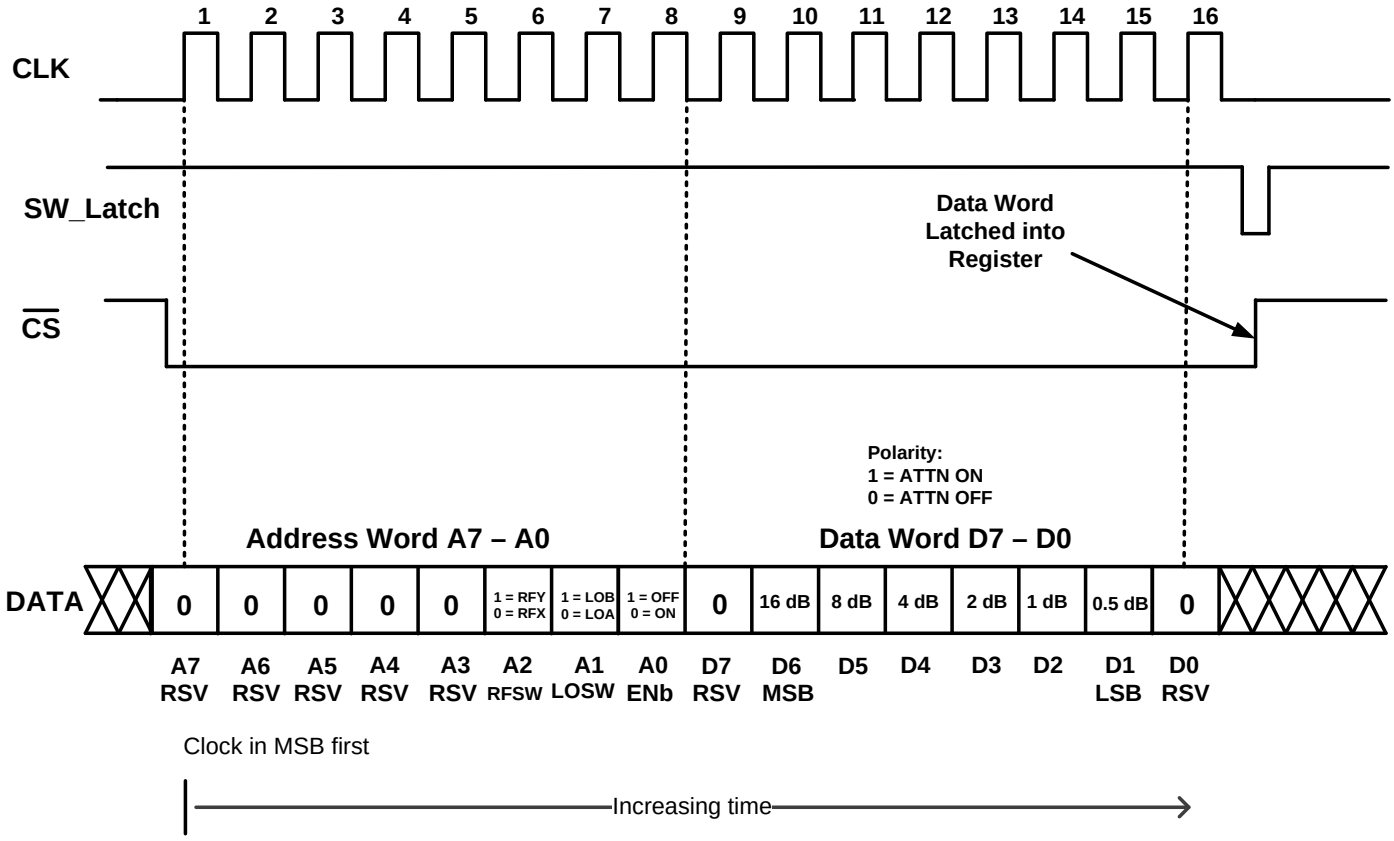
The default state after using power-on sequence:

- Maximum attenuation
- RF_INX, LO_INA selected
- Normal operation (not Standby Mode)

SERIAL PROGRAMMING

The device is programmed via the serial port by asserting Chip Select (CSb). Note: Most-Significant-Bit first, where the Address Word is the Most-Significant-Byte.

Serial mode timing diagram high level:

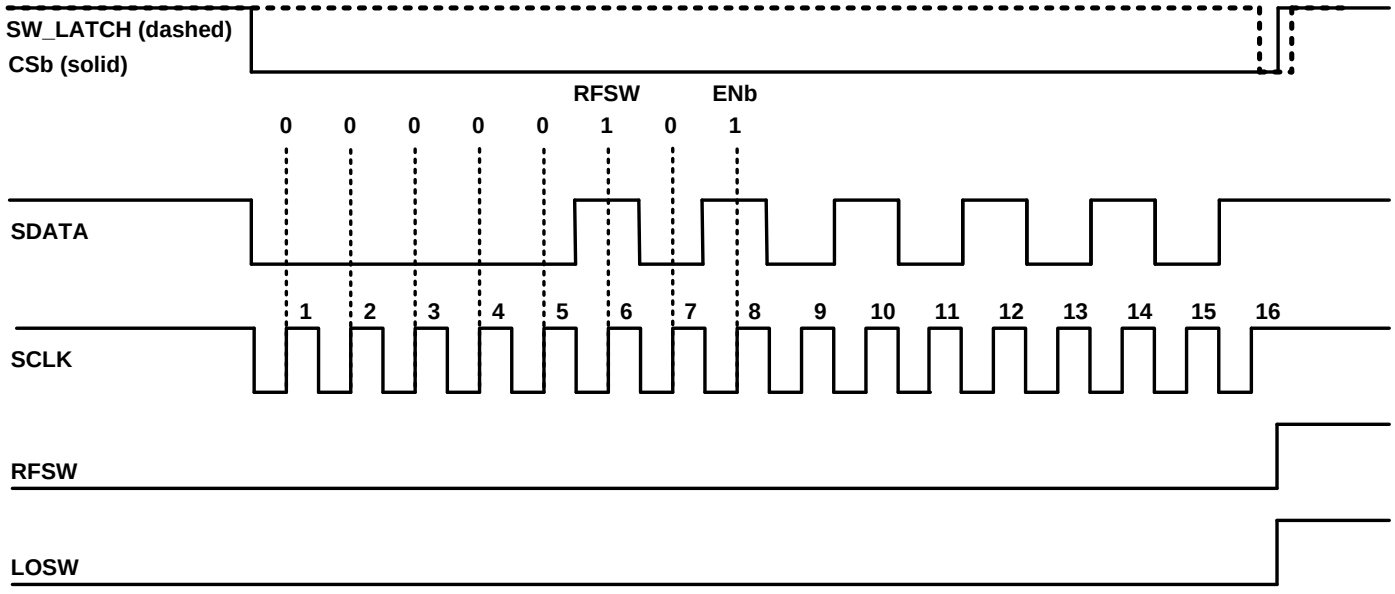


TO PROGRAM THE SERIAL INTERFACE:

If CSb is de-asserted (set to high), the serial interface will ignore the CLK line. Once CSb is asserted (set to low), the serial interface will recognize the CLK and any data present on DATA will be clocked into the registers with each rising CLK edge. After the 16th CLK cycle, and before the 17th CLK cycle, CSb must be de-asserted to successfully program the part with the desired bytes. If CSb is de-asserted before the 16th CLK cycle, or after the 17th CLK cycle, there is no guarantee that the correct bytes will be programmed and the user will have to re-program the interface in accordance with the aforementioned procedure.

SW_LATCH PROGRAMMING SEQUENCE

- When SW_LATCH is pinned high during the programming sequence, "RFSW" and "ENb" registers cannot be programmed and therefore will not toggle.
- If SW_LATCH is pinned low during the programming sequence, the "RFSW" and "ENb" register will toggle. This can be prevented with the "Programming Sequence" below.



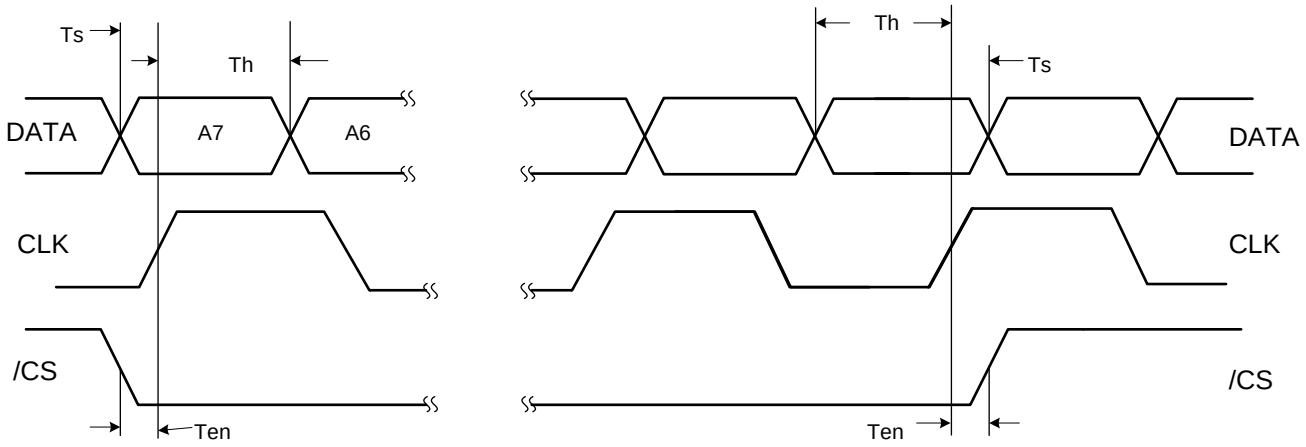
SEQUENCE FOR PROGRAMMING REGISTERS A<2>:A<0>

1) SW_Latch = 1; CSb = 0
2) CLK in 8- or 16-bit word, *do not de-assert (pull high) CSb*
3) Set SW_LATCH = 0 while CSb = 0 remains)
4) With SW_Latch = 0, set CSb = 1
5) Set SW_Latch = 1
6) Program complete

SPECIAL NOTE REGARDING PHASE OF I & Q:

- When LO is high-side injected, IF_I leads IF_Q by 90 degrees
- When LO is low-side injected, IF_Q leads IF_I by 90 degrees

SERIAL MODE TIMING DIAGRAM ZOOM:



- Data is shifted with the rising edge of CLK when /CS is low
- The rising edge of /CS latches data into the device

LOGIC TRUTH TABLE:

STBY	SW_LATCH	MODE	WRITE ACCESS
0	0	Operating Mode	A2:A0 Enabled, D7:D0 Enabled
0	1	Operating Mode	A2:A0 Disabled, D7:D0 Enabled
1	0	Off	A2:A0 Enabled, D7:D0 Enabled
1	1	Off	A2:A0 Disabled, D7:D0 Enabled

F1300 ATTENUATION TABLE

The F1300 gain/attenuation setting is controlled by 6 bits in the data word. The device provides an added attenuation range from 0 dB to 25.5 dB in 0.5 dB steps. A “high” or “1” bit corresponds to attenuation stepped IN, while a “low” or “0” bit corresponds to attenuation stepped OUT.

F1300 DPD Demodulator - Attenuation Table (Data Word D7-D0)

BINARY	HEX	Added Atten (dB)		BINARY	HEX	Added Atten (dB)
00000000	00	0		00110100	34	13
00000010	02	0.5		00110110	36	13.5
00000100	04	1		00111000	38	14
00000110	06	1.5		00111010	3A	14.5
00001000	08	2		00111100	3C	15
00001010	0A	2.5		00111110	3E	15.5
00001100	0C	3		01000000	40	16
00001110	0E	3.5		01000010	42	16.5
00010000	10	4		01000100	44	17
00010010	12	4.5		01000110	46	17.5
00010100	14	5		01001000	48	18
00010110	16	5.5		01001010	4A	18.5
00011000	18	6		01001100	4C	19
00011010	1A	6.5		01001110	4E	19.5
00011100	1C	7		01010000	50	20
00011110	1E	7.5		01010010	52	20.5
00100000	20	8		01010100	54	21
00100010	22	8.5		01010110	56	21.5
00100100	24	9		01011000	58	22
00100110	26	9.5		01011010	5A	22.5
00101000	28	10		01011100	5C	23
00101010	2A	10.5		01011110	5E	23.5
00101100	2C	11		01100000	60	24
00101110	2E	11.5		01100010	62	24.5
00110000	30	12		01100100	64	25
00110010	32	12.5		01100110	66	25.5

Because the first and last bits of the Data Word are not presently used by the F1300, two additional hex character pairs exists for each of those in this table. For example, data words of either H00, H80, or H01 (binary “00000000,” “10000000,” or 00000001) will place the F1300 in its minimum attenuation state. Likewise, data words of either H66, HE6, or H67 (binary “01100110” or “11100110” or “01100111”) will place the F1300 in its maximum attenuation state of 25.5 added attenuation.

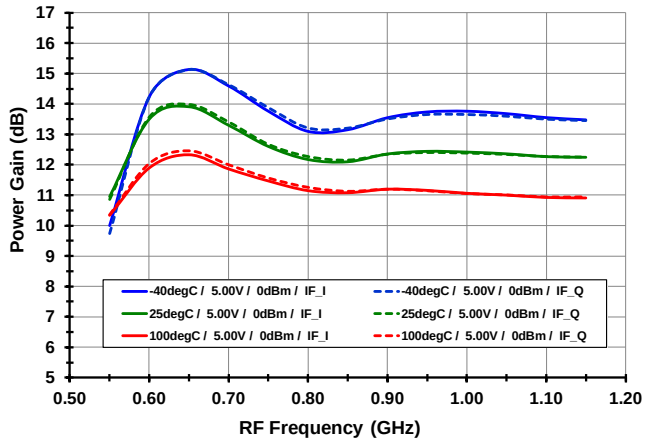
TYPICAL OPERATING CONDITIONS

Unless otherwise noted, for the TOC graphs, the following conditions apply

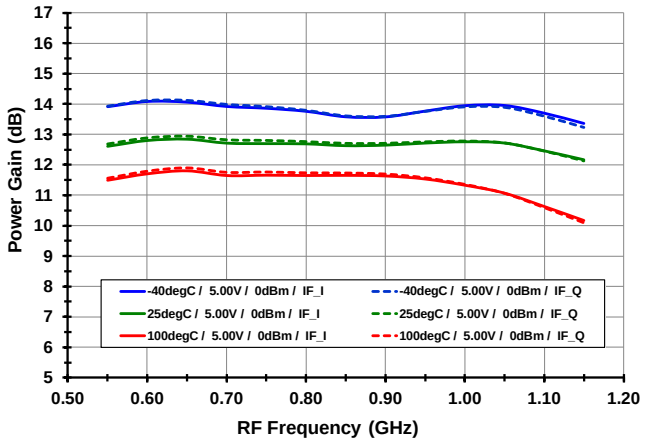
- **IF = 200 MHz**
- **Tone spacing = 5 MHz**
- **Pout ~ 1 dBm**
- **Pin = -11 dBm**
- **RF_X, LO_A, IF_I selected**
- **Attenuation Setting = 0 dB (min ATTN or G_{MAX})**
- **T_{CASE} = 25C**
- **V_{CC} = 5.00 V**
- **LO level = 0 dBm**
- **Output Transformer losses are de-embedded**
- **Input RF trace losses are de-embedded**

TOCs [Fixed IF] (-1-)

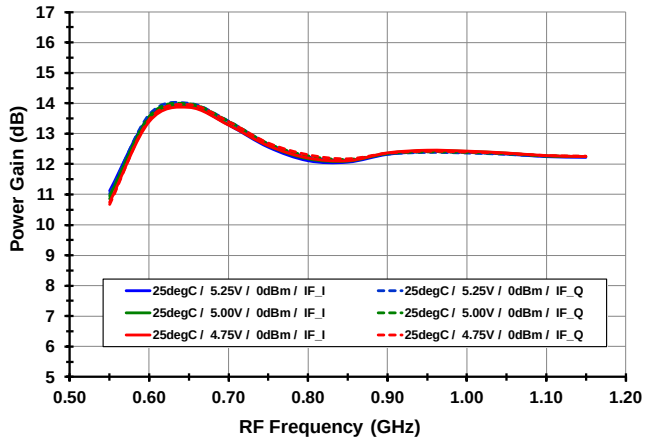
GAIN vs. T_{CASE} [*Low* Side Injection]



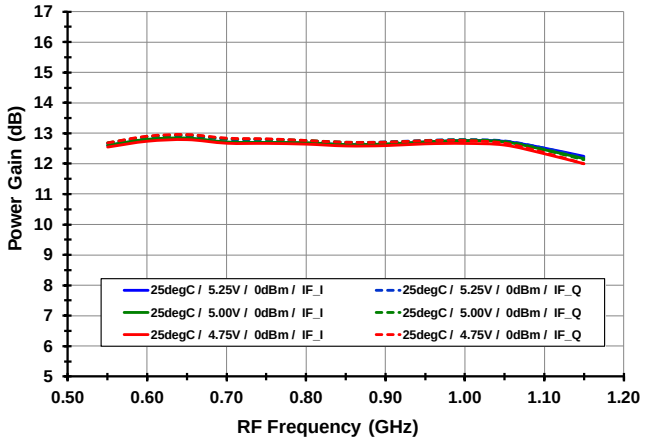
GAIN vs. T_{CASE} [*High* Side Injection]



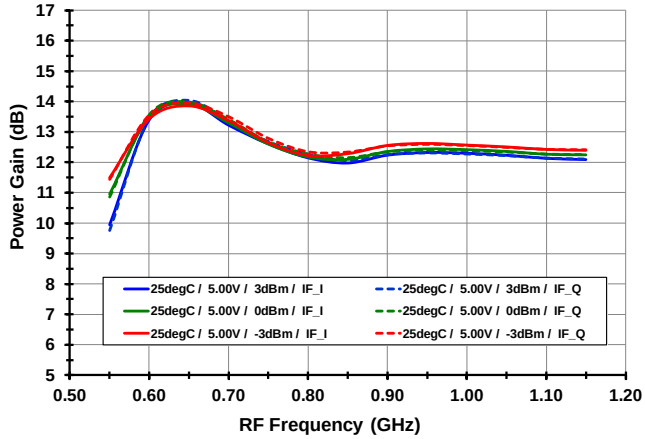
GAIN vs. V_{CC} [*Low* Side Injection]



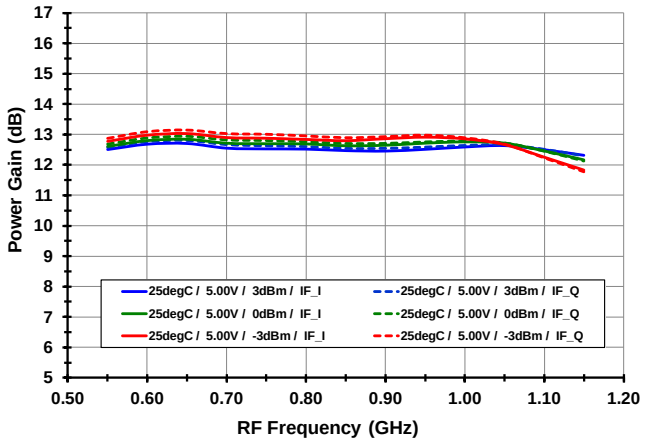
GAIN vs. V_{CC} [*High* Side Injection]



GAIN vs. LO level [*Low* Side Injection]

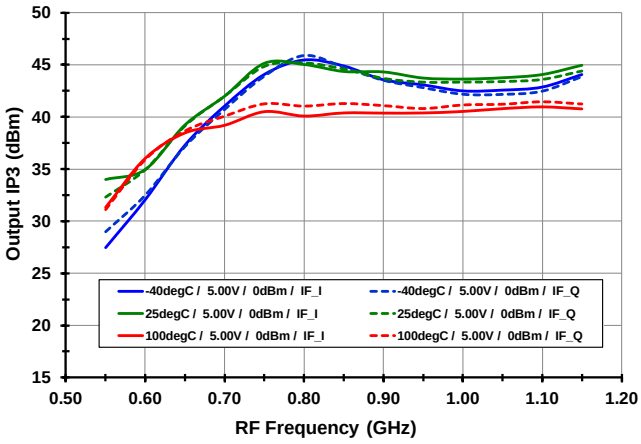


GAIN vs. LO level [*High* Side Injection]

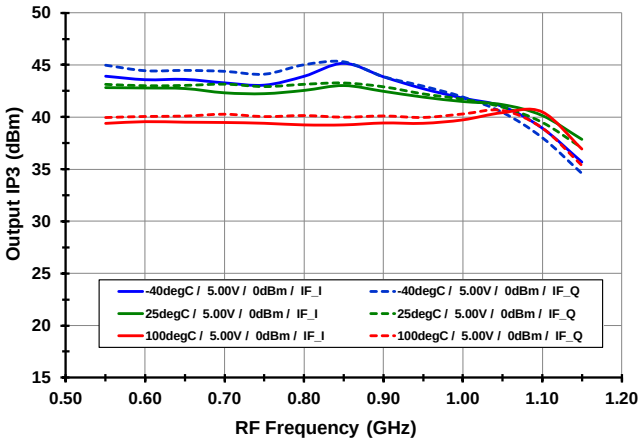


TOCs [Fixed IF] (-2-)

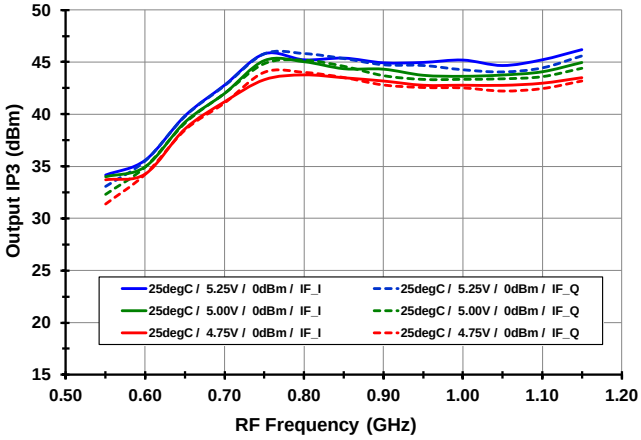
IP3O vs. TCASE [*Low* Side Injection]



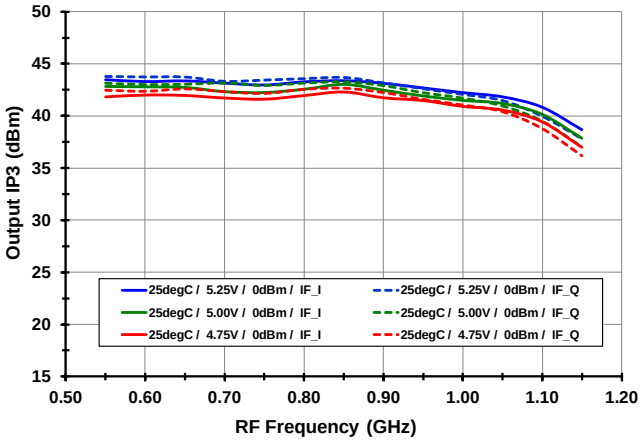
IP3O vs. TCASE [*High* Side Injection]



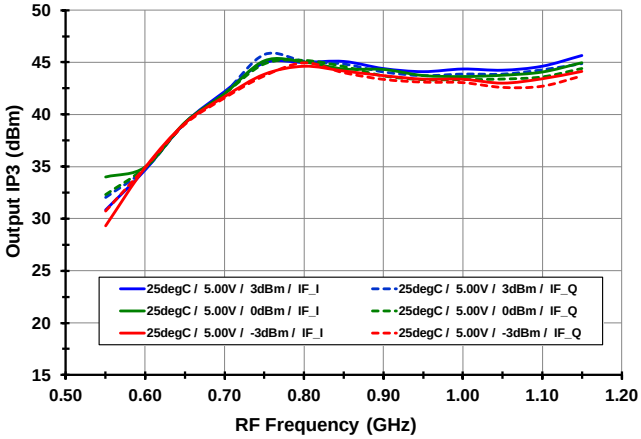
IP3O vs. VCC [*Low* Side Injection]



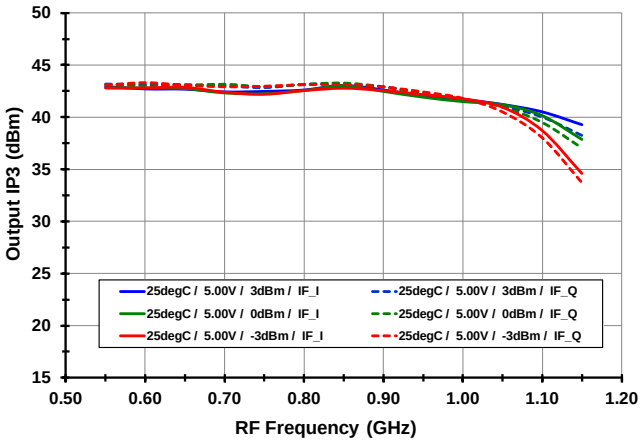
IP3O vs. VCC [*High* Side Injection]



IP3O vs. LO level [*Low* Side Injection]

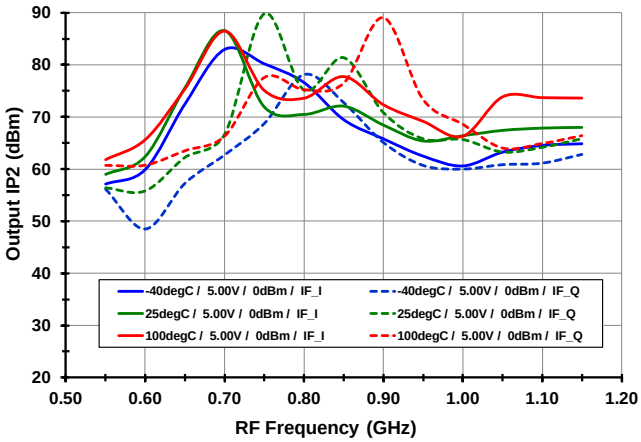


IP3O vs. LO level [*High* Side Injection]

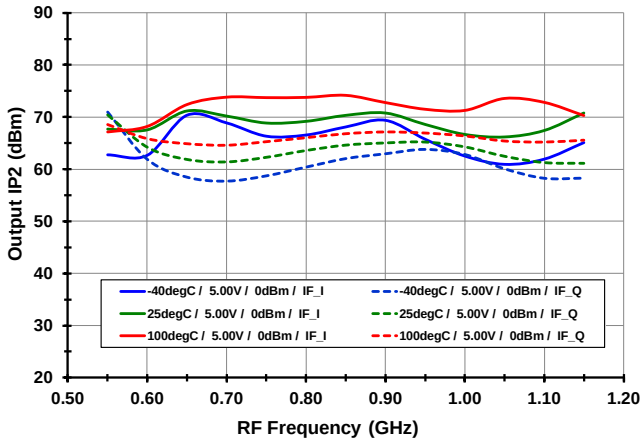


TOCs [Fixed IF] (-3-)

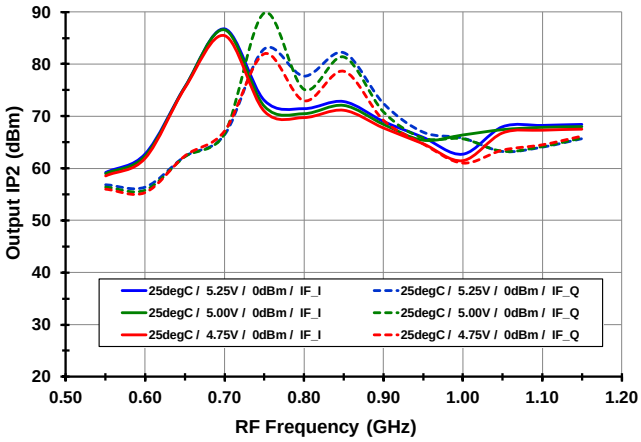
IP2O vs. TCASE [*Low* Side Injection]



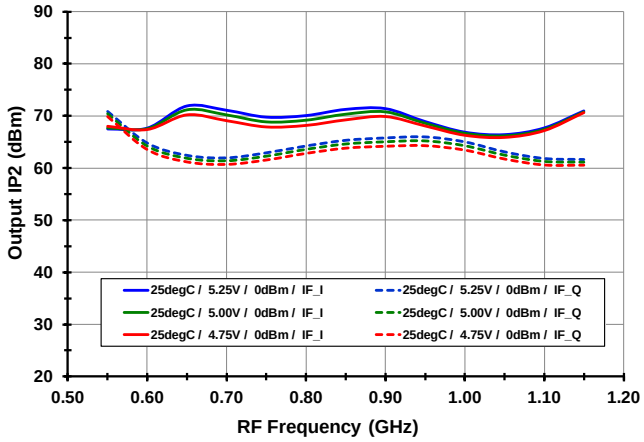
IP2O vs. TCASE [*High* Side Injection]



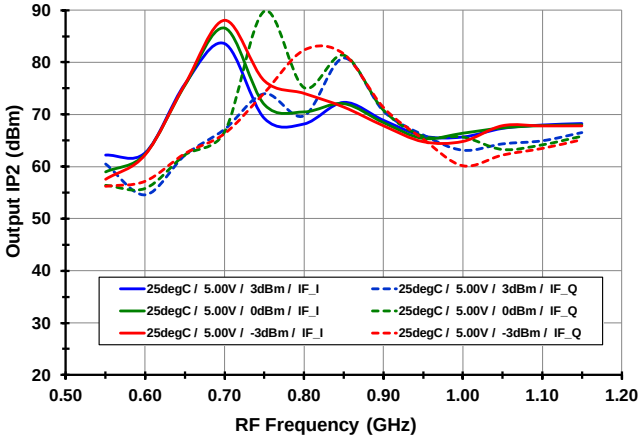
IP2O vs. VCC [*Low* Side Injection]



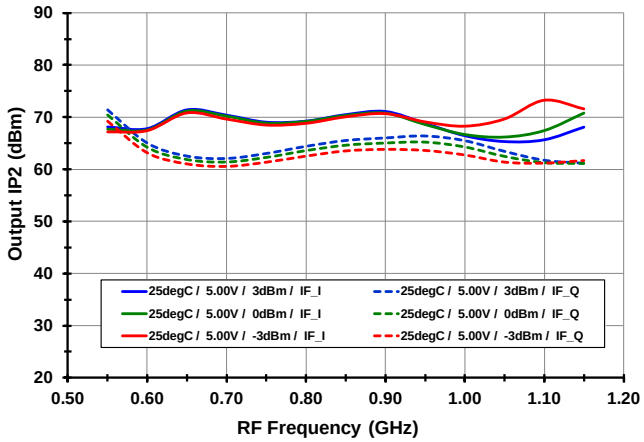
IP2O vs. VCC [*High* Side Injection]



IP2O vs. LO level [*Low* Side Injection]

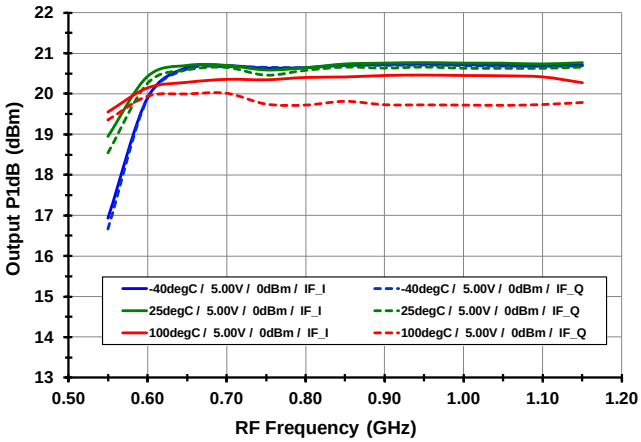


IP2O vs. LO level [*High* Side Injection]

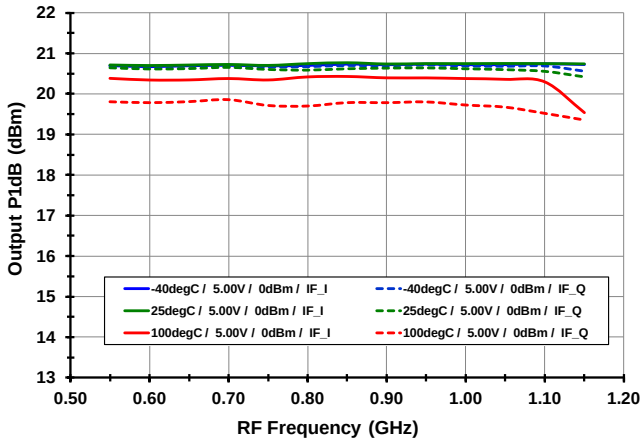


TOCs [Fixed IF] (-4-)

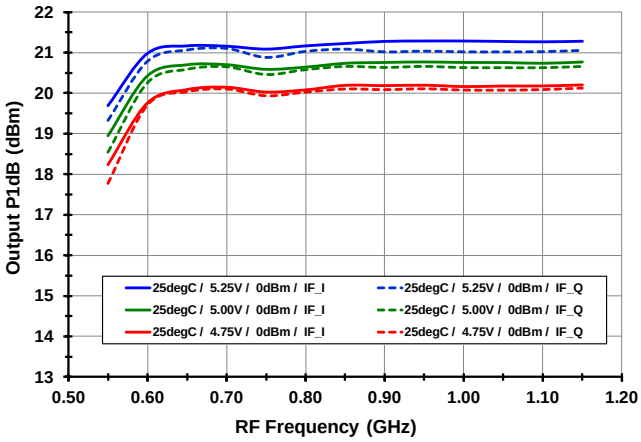
P1dB$_O$ vs. T$_{CASE}$ [*Low* Side Injection]



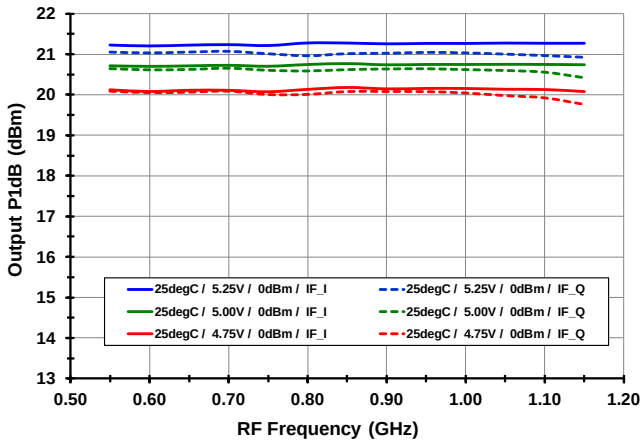
P1dB$_O$ vs. T$_{CASE}$ [*High* Side Injection]



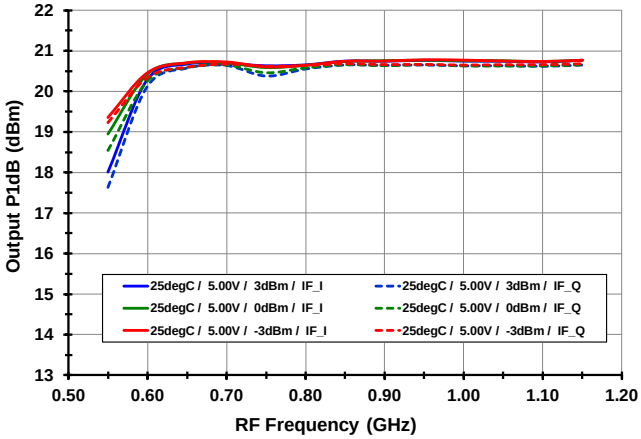
P1dB$_O$ vs. V$_{CC}$ [*Low* Side Injection]



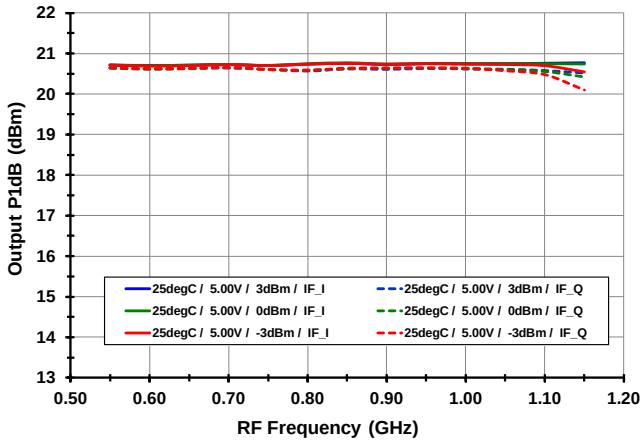
P1dB$_O$ vs. V$_{CC}$ [*High* Side Injection]



P1dB$_O$ vs. LO level [*Low* Side Injection]

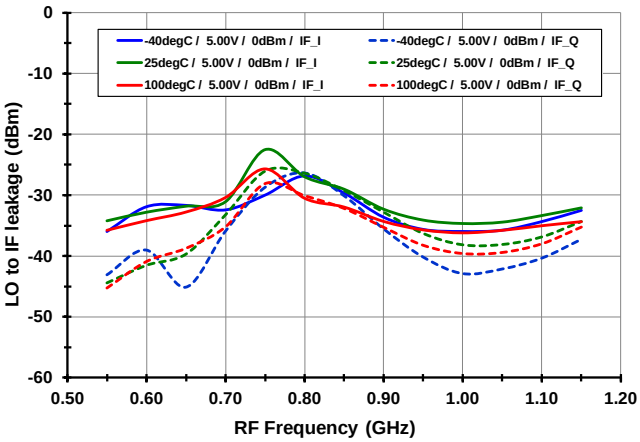


P1dB$_O$ vs. LO level [*High* Side Injection]

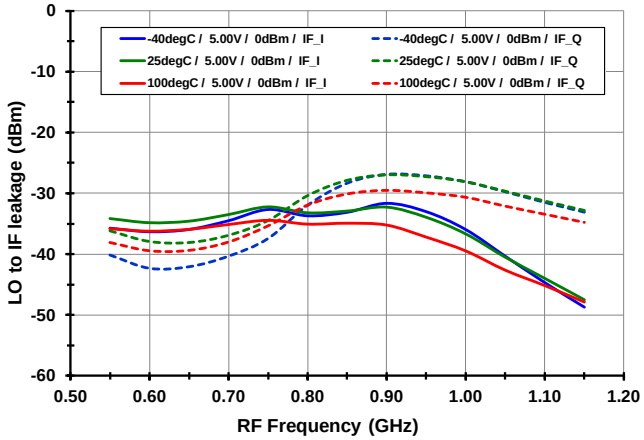


TOCs [Fixed IF] (-5-)

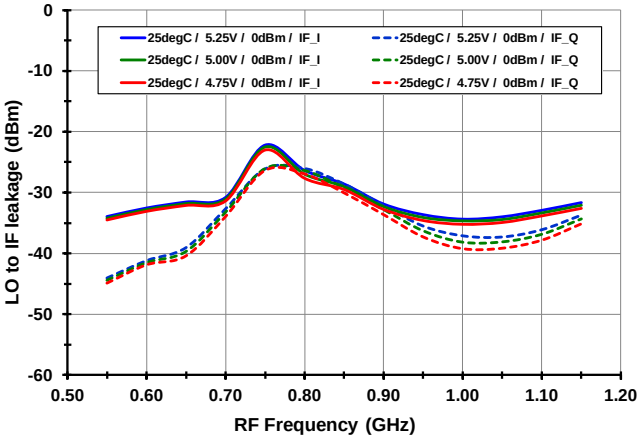
LO to IF vs. T_{CASE} [*Low* Side Injection]



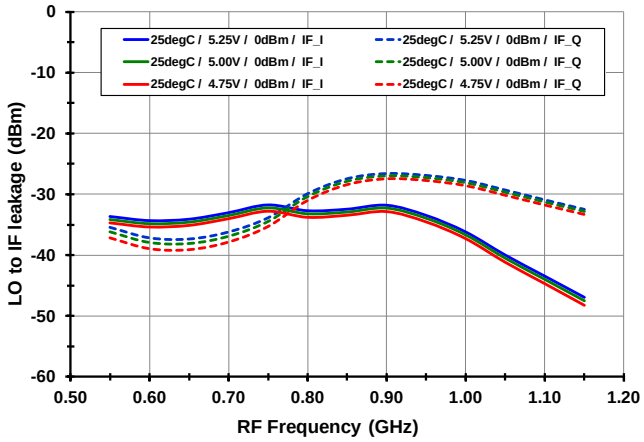
LO to IF vs. T_{CASE} [*High* Side Injection]



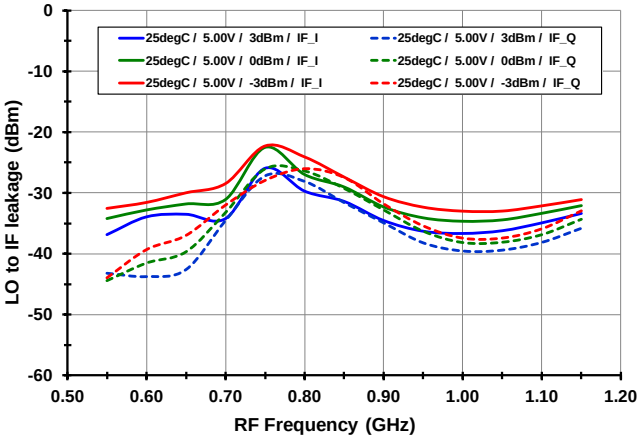
LO to IF vs. V_{CC} [*Low* Side Injection]



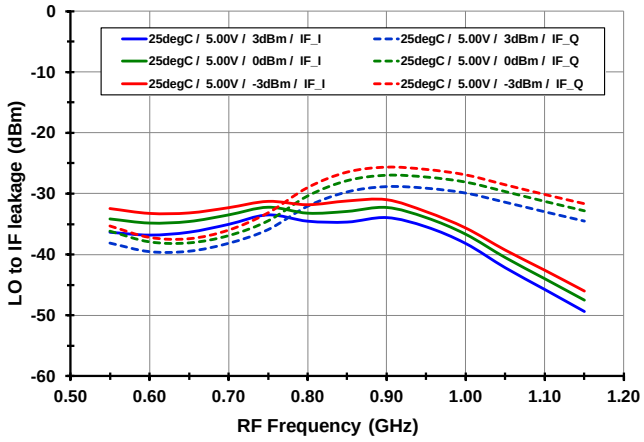
LO to IF vs. V_{CC} [*High* Side Injection]



LO to IF vs. LO level [*Low* Side Injection]

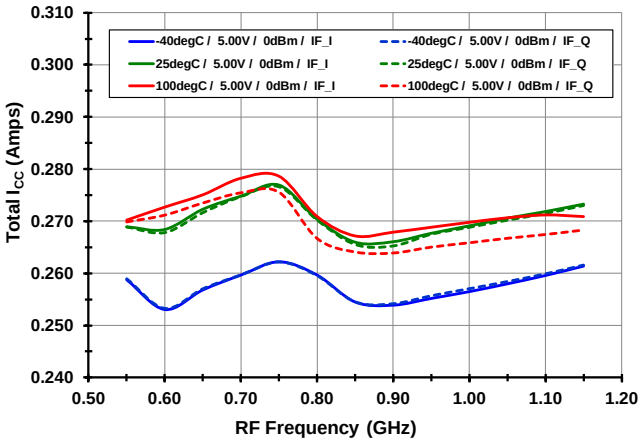


LO to IF vs. LO level [*High* Side Injection]

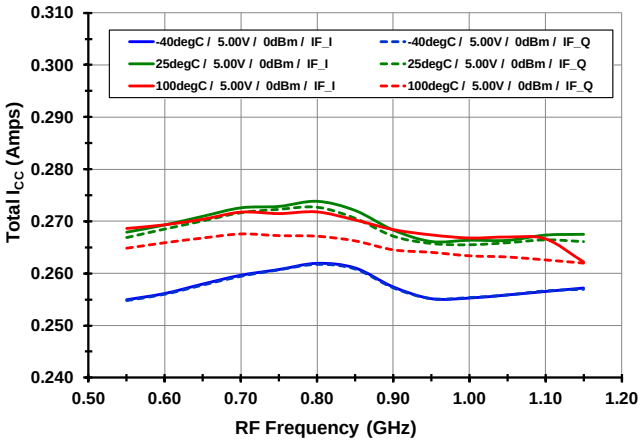


TOCs [Fixed IF] (-6-)

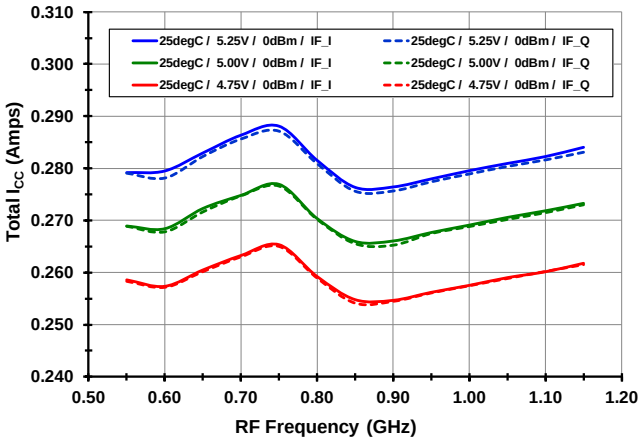
I_{CC} vs. T_{CASE} [*Low* Side Injection]



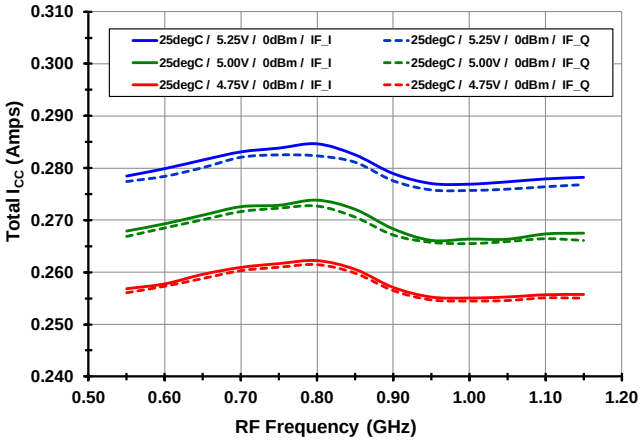
I_{CC} vs. T_{CASE} [*High* Side Injection]



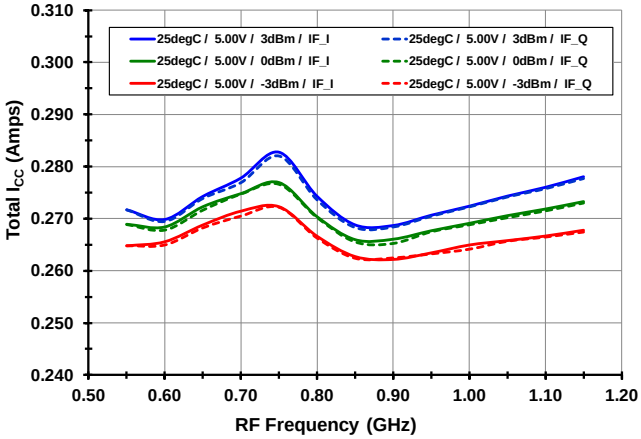
I_{CC} vs. V_{CC} [*Low* Side Injection]



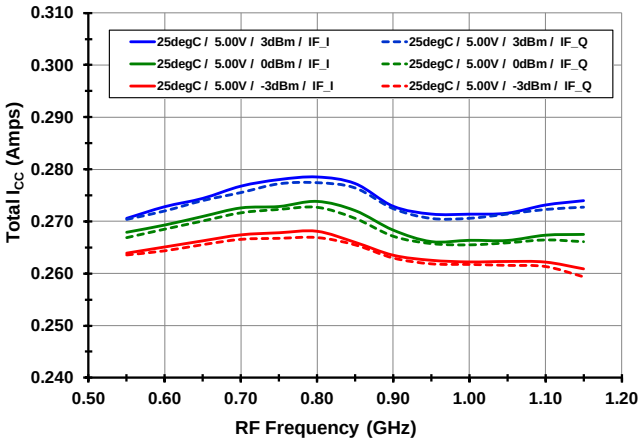
I_{CC} vs. V_{CC} [*High* Side Injection]



I_{CC} vs. LO level [*Low* Side Injection]

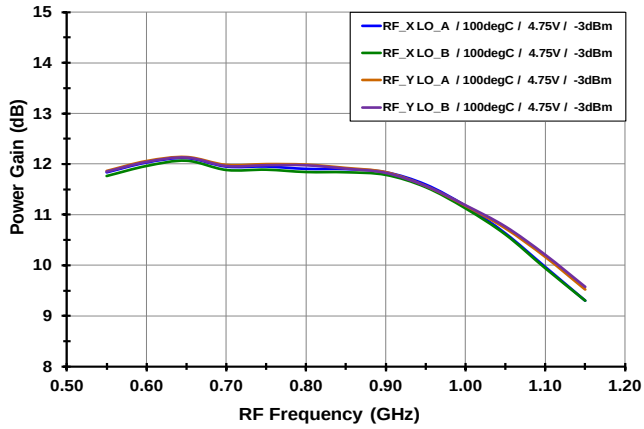


I_{CC} vs. LO level [*High* Side Injection]

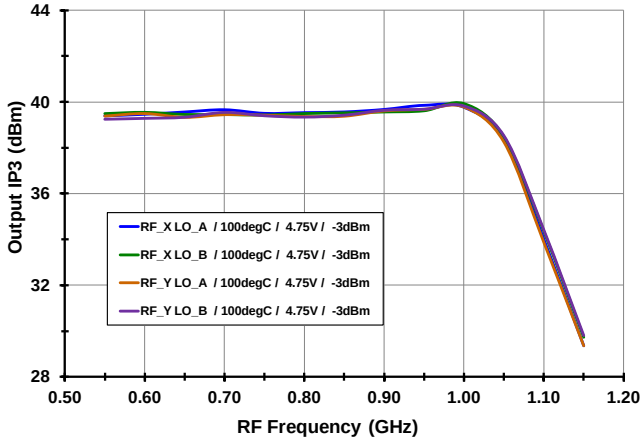


TOCs [vs. Switch Configuration, Extreme Conditions, IF_I only] (-7-)

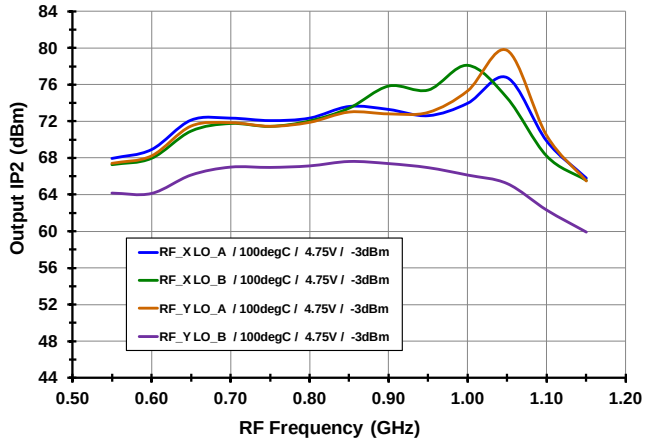
Gain [*High* Side Injection]



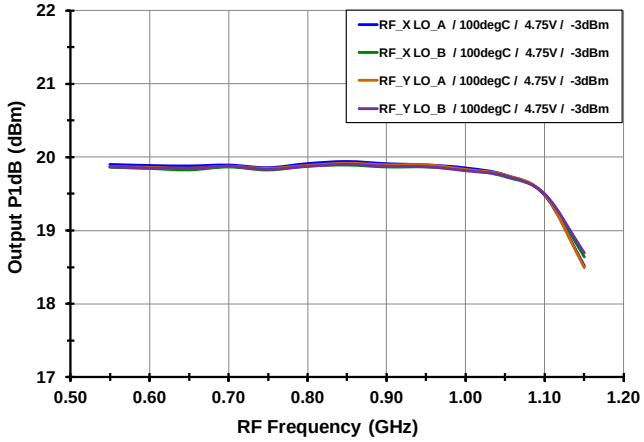
Output IP3 [*High* Side Injection]



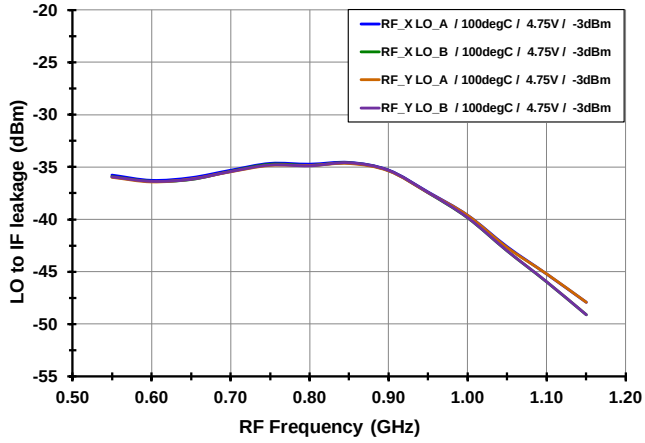
Output IP2 [*High* Side Injection]



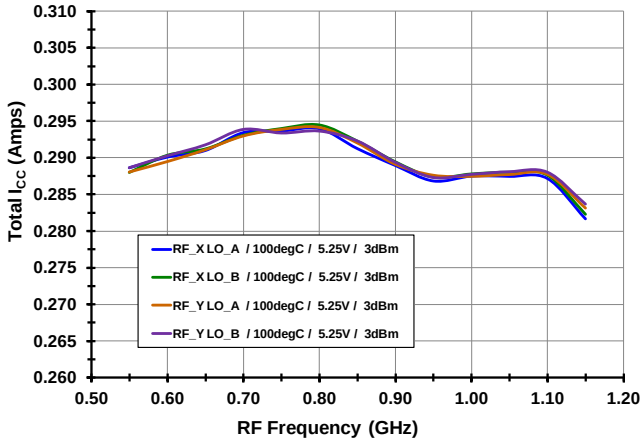
Output P1dB [*High* Side Injection]



LO to IF [*High* Side Injection]

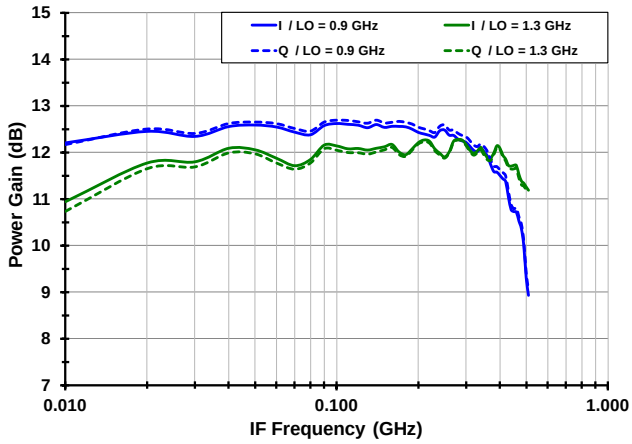


I_{CC} [*High* Side Injection]

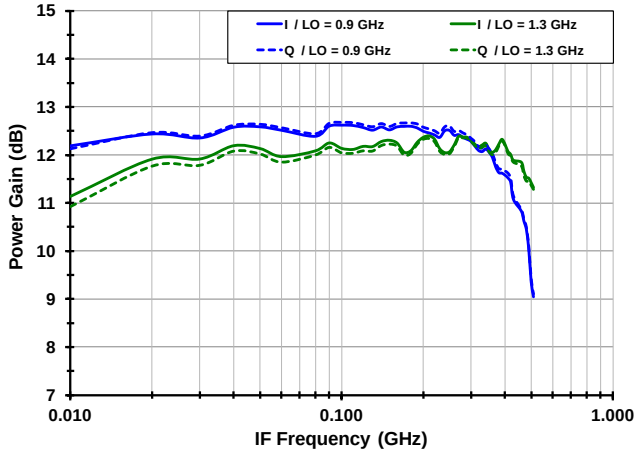


TOCs [Fixed LO] (-8-)

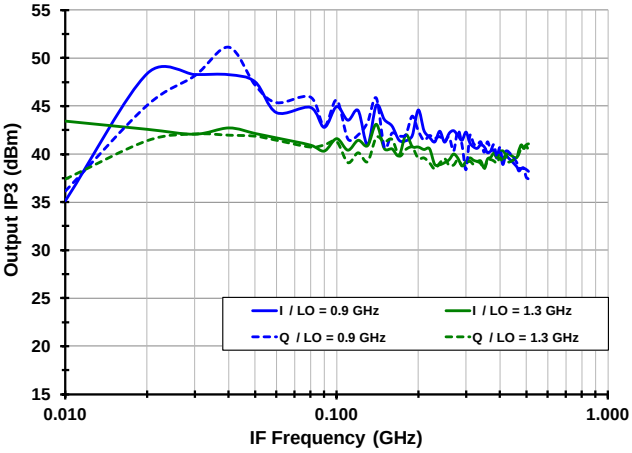
Gain Flatness [*High* Side Injection, RF_X LO_A]



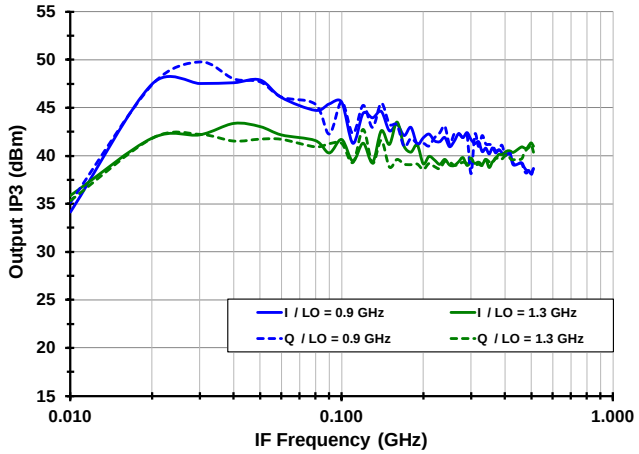
Gain Flatness [*High* Side Injection, RF_Y LO_B]



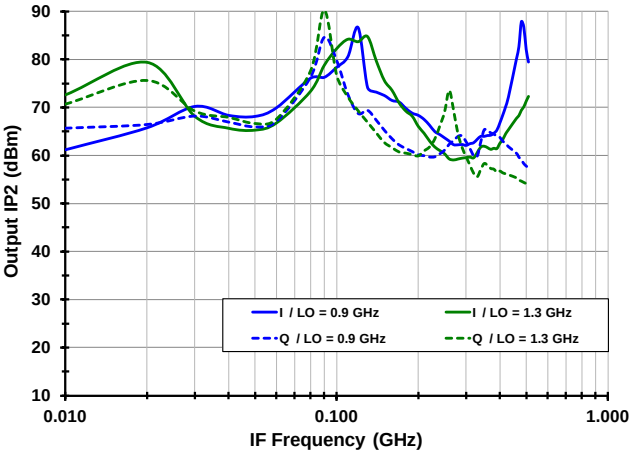
IP3O Flatness [*High* Side Injection, RF_X LO_A]



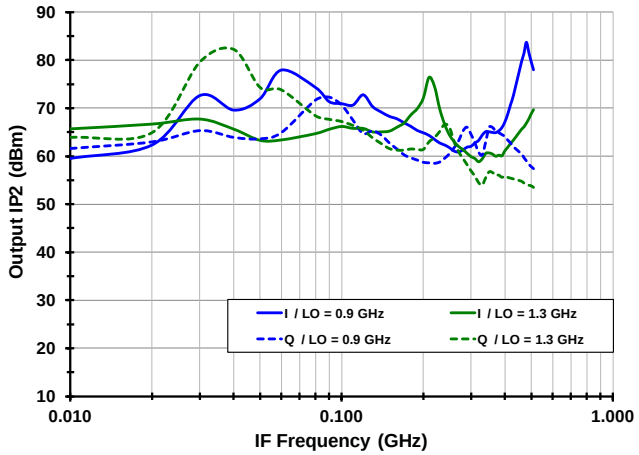
IP3O Flatness [*High* Side Injection, RF_Y LO_B]



IP2O Flatness [*High* Side Injection, RF_X LO_A]

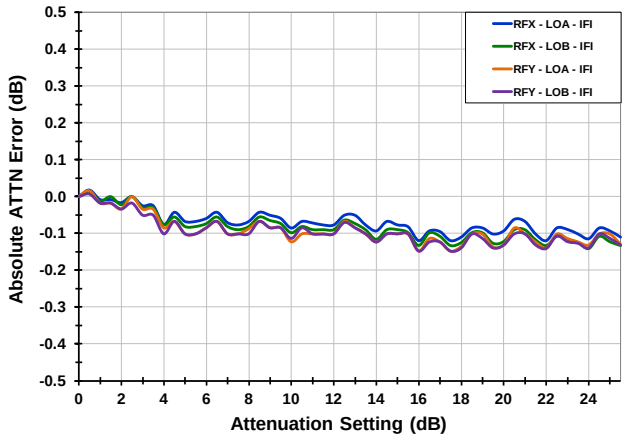


IP2O Flatness [*High* Side Injection, RF_Y LO_B]

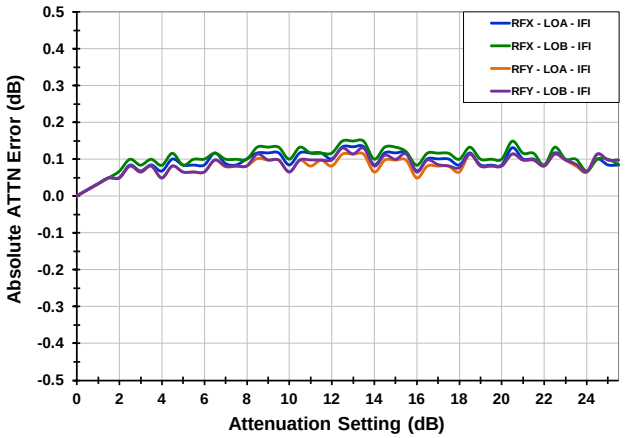


TOCs [vs. Attenuation Setting] (-9-)

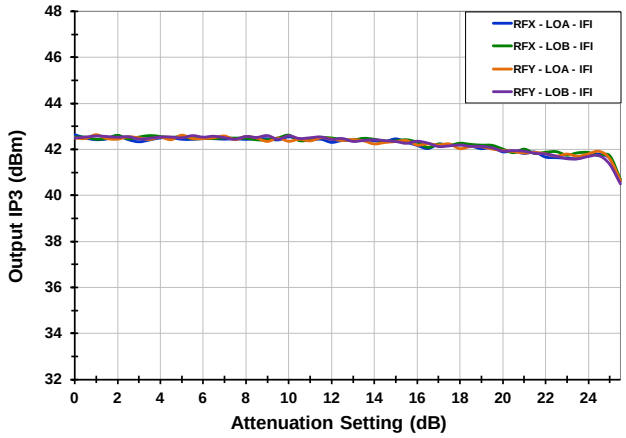
ATTN Accuracy [0.8 GHz RF, *HiSide* Inj.]



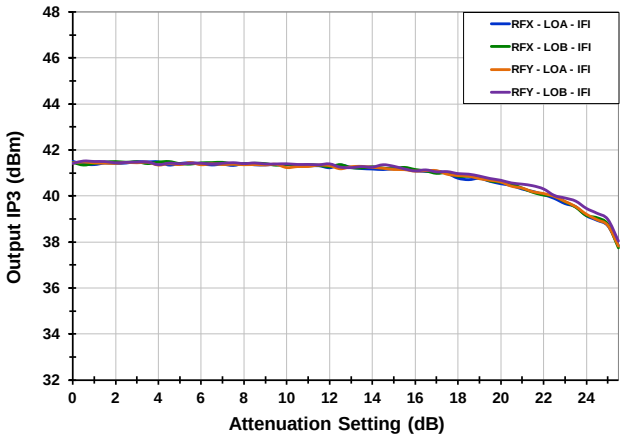
ATTN Accuracy [1.0 GHz RF, *HiSide* Inj.]



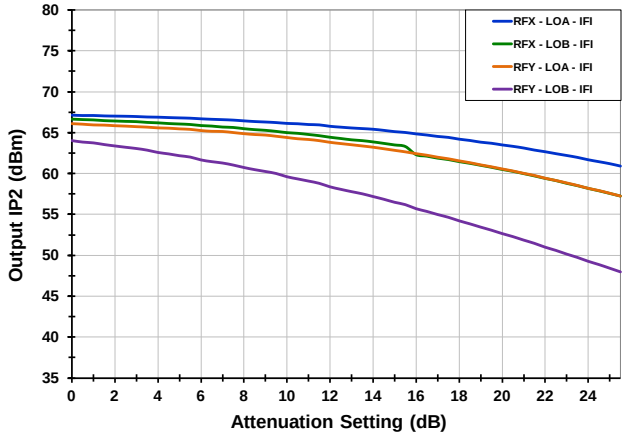
IP3O [0.8 GHz RF, *HiSide* Inj.]



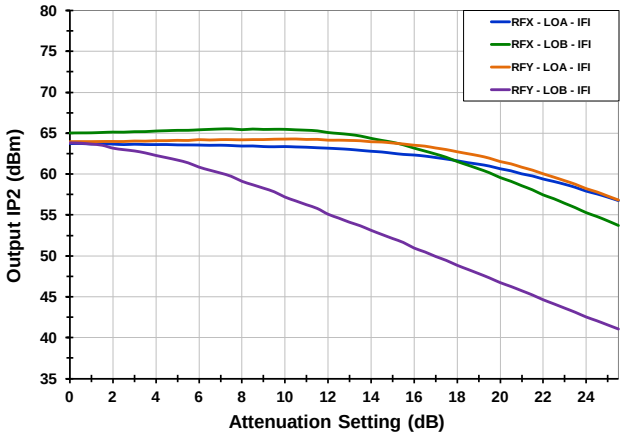
IP3O [1.0 GHz RF, *HiSide* Inj.]



IP2O [0.8 GHz RF, *HiSide* Inj.]

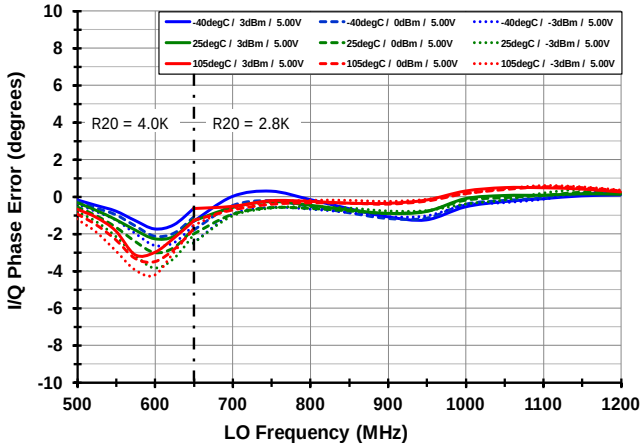


IP2O [1.0 GHz RF, *HiSide* Inj.]

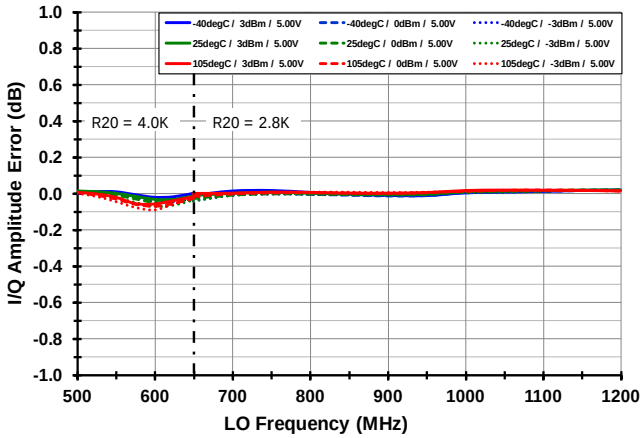


TOCs [Quadrature] (-10-)

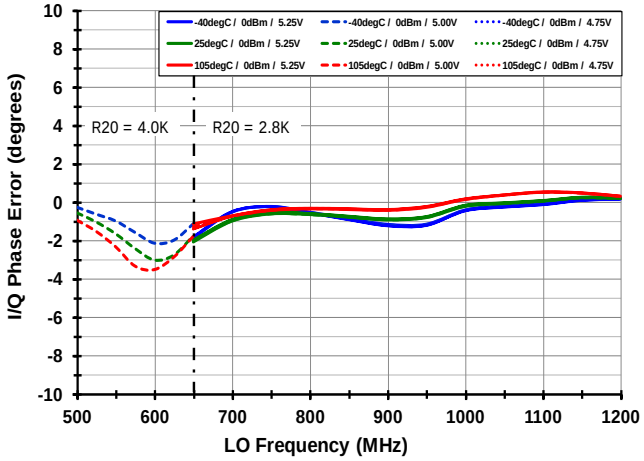
I/Q Phase Error vs. LO Level & T_{CASE}



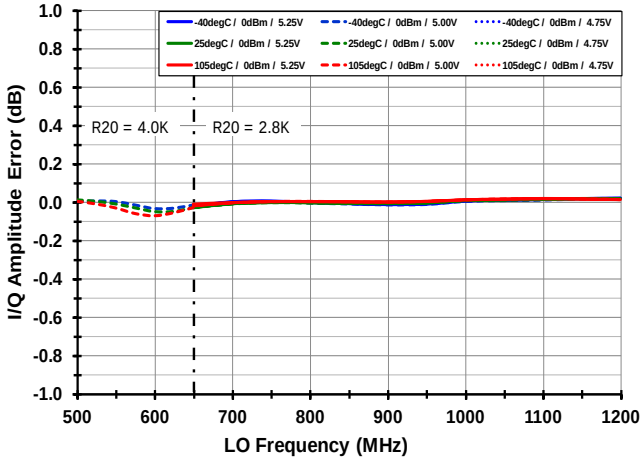
I/Q Amplitude Error vs. LO Level & T_{CASE}



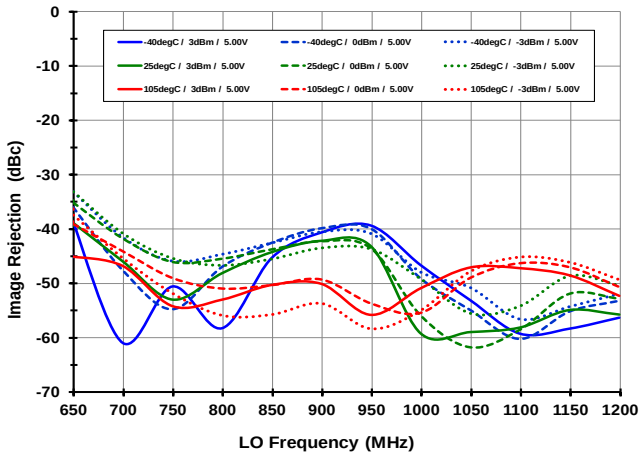
I/Q Phase Error vs. V_{CC} & T_{CASE}



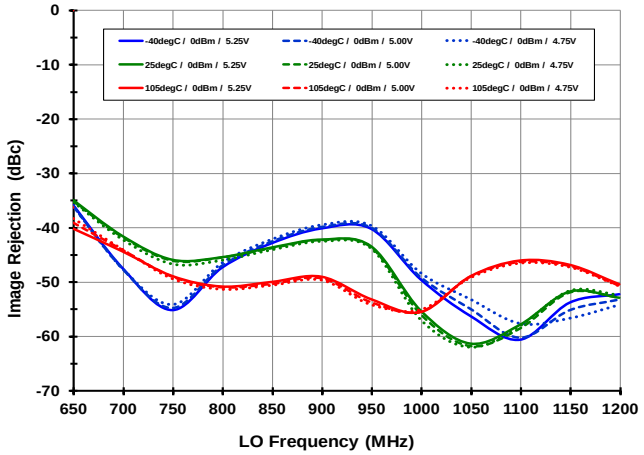
I/Q Amplitude Error vs. V_{CC} & T_{CASE}



I/Q Image Rejection vs. LO Level & T_{CASE}

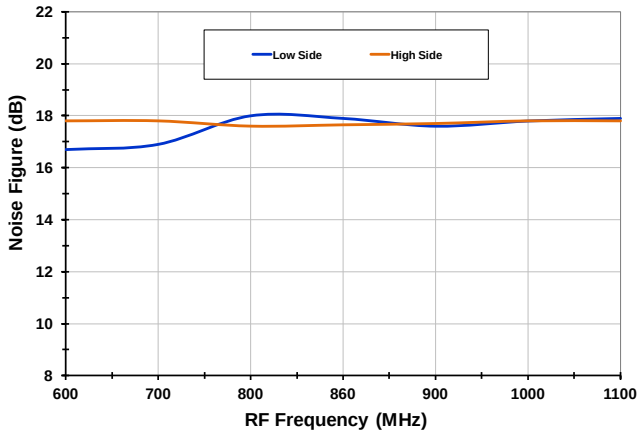


I/Q Image Rejection vs. V_{CC} & T_{CASE}

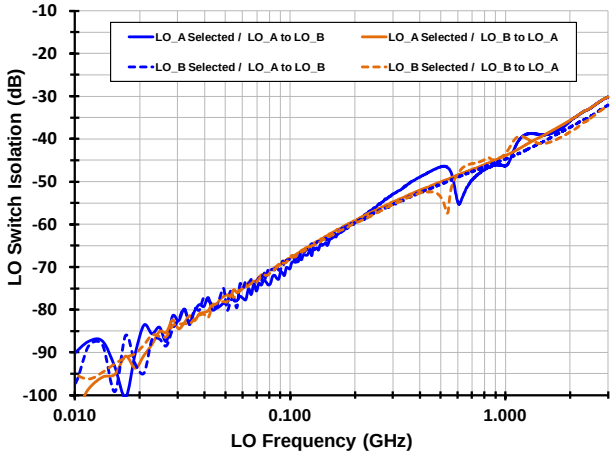


TOCs [NF, Switch Iso, Port Matches] (-11-)

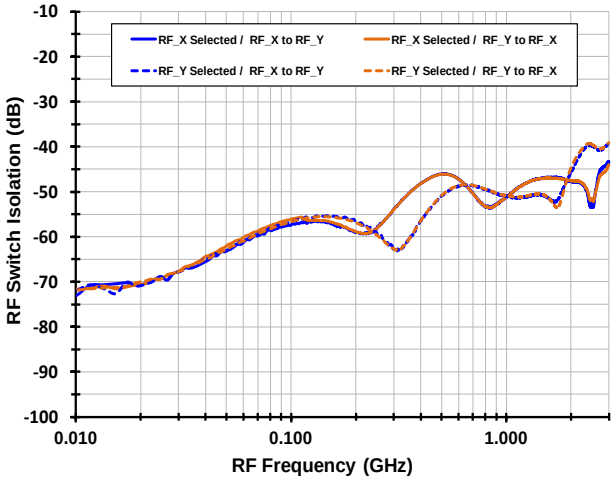
Noise Figure



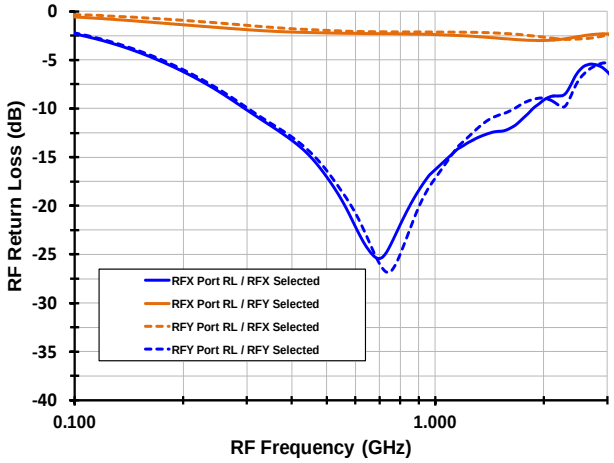
LO Switch Isolation



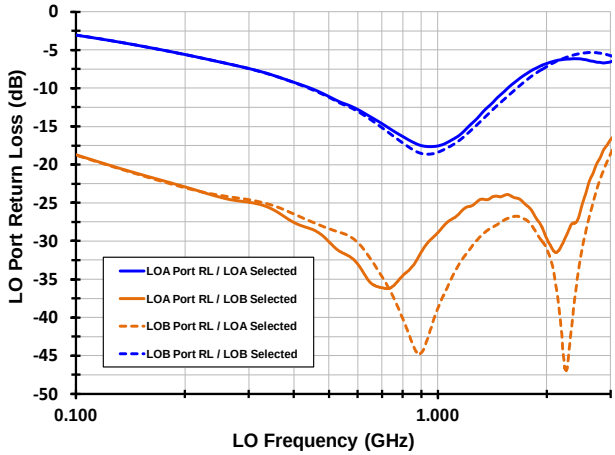
RF Switch Isolation



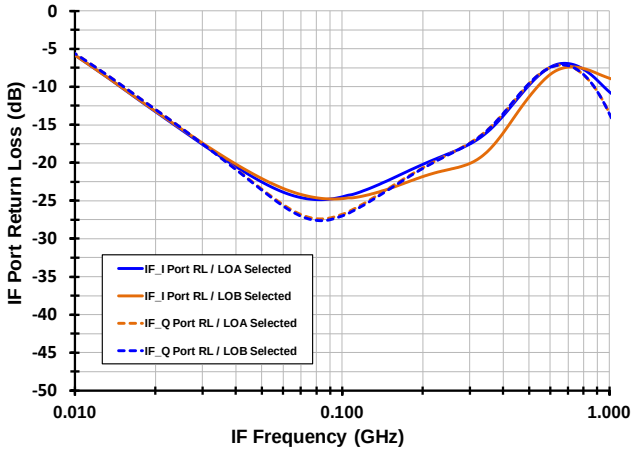
RF Port Return Loss [LO=1.06 GHz, LOA selected]



LO Port Return Loss



IF Port Return Loss



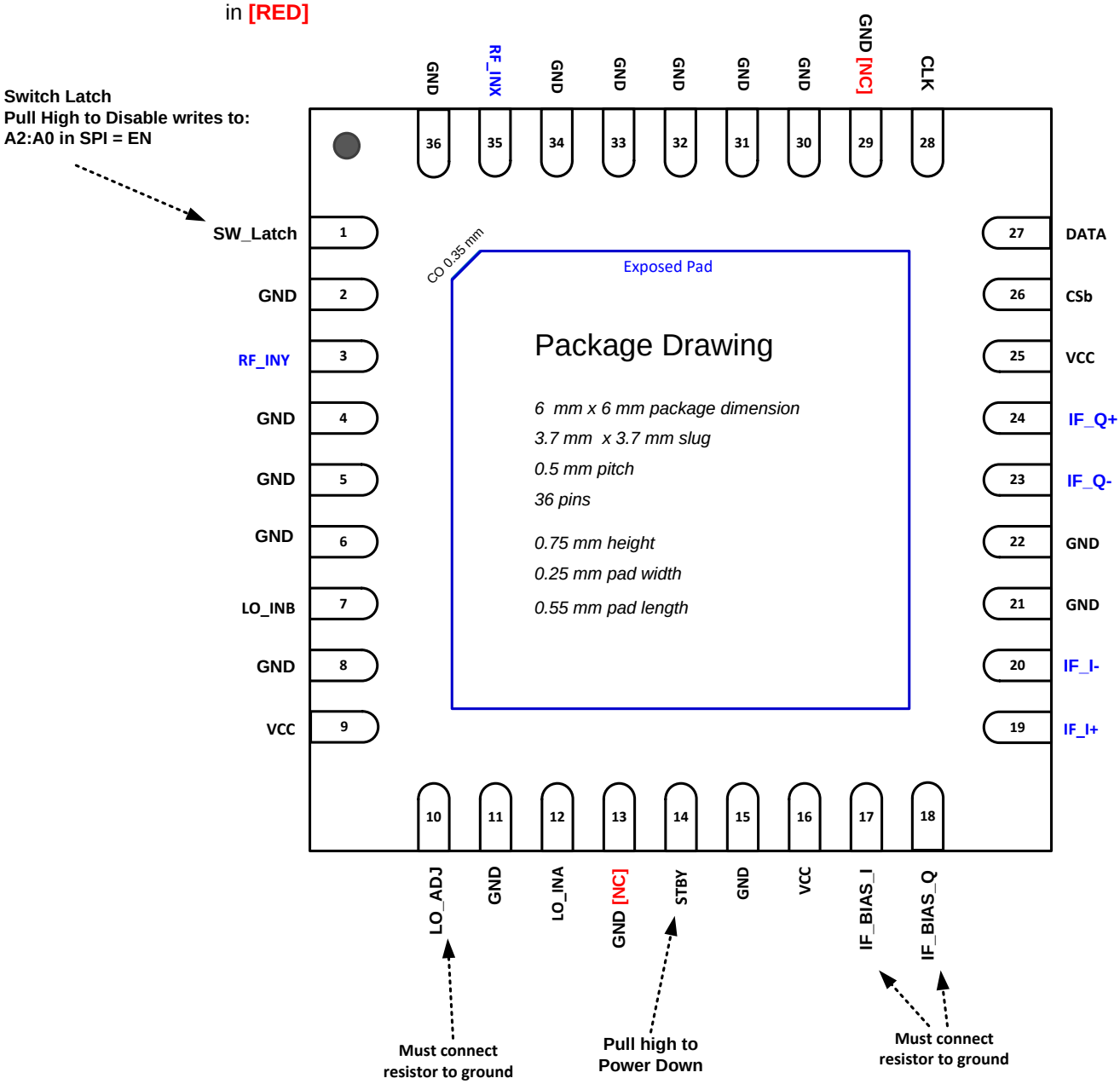
PACKAGE OUTLINE DRAWINGS

The package outline drawings are located at the end of this document and are accessible from the Renesas website The package information is the most current data available and is subject to change without revision of this document.

PIN DIAGRAM

Signal Path Inputs & Outputs in **BLUE**

Internal Connections in **[RED]**



PIN DESCRIPTIONS

Pins	Name	Function
1	SW_LATCH	Stand-by latch. Pull Low or Ground for Normal Operation. If left floating, this input will be internally pulled high, disabling SPI writes to ENb (Standby) and RF SW bits (A0, A2).
2, 4, 5, 6, 8, 11,15, 21, 22, 30, 31, 32, 33, 34, 36	GND	Ground these Pins.
3	RF_INY	Alternate RF Input. Separated from RF_INX by internal SP2T. AC couple to this pin. Internally matched to 50 ohms
7	LO_INB	LO Input B. AC couple to this pin. Internally matched to 50 ohms. Selected via SPI port.
9, 16, 25	VCC	Power Supply. Bypass to GND with capacitors shown in the Typical Application Circuit as close as possible to pin.
10	LO_ADJ	Connect the specified resistor from this pin to ground to set the LO path I_{CC}. This IS a current setting resistor
12	LO_INA	LO Input A. AC couple to this pin. Internally matched to 50 ohms. Selected via SPI port.
13, 29	N.C.	No Connection. Not internally connected. OK to connect to Vcc. Recommended Connection is Ground
14	STBY	STBY Mode. Pull this pin high for Standby mode (30mA). Pull low or Ground for normal Operation
17, 18	IF_BIAS_I IF_BIAS_Q	Connect the specified resistor from this pin to ground to set the IF amplifier bias reference. This is NOT a current setting resistor
19, 20	IF_I+, IF_I-	*In-Phase* Mixer Differential IF Output. Connect pullup inductors from each of these pins to V_{CC} (see the Typical Application Circuit).
23, 24	IF_Q-, IF_Q+	*Quadrature* Mixer Differential IF Output. Connect pullup inductors from each of these pins to V_{CC} (see the Typical Application Circuit).
26	CSb	Chip Select Bar. The falling edge initiates a programming cycle and the rising edge latches the programmed shift register data into the active register.
27	DATA	Serial Data Input
28	CLK	Serial Clock Input
35	RF_INX	Main RF Input. Separated from RF_INY by internal SP2T. AC couple to this pin. Internally matched to 50 ohms
	— EP	Exposed Pad. Internally connected to GND. Solder this exposed pad to a PCB pad that uses multiple ground vias to provide heat transfer out of the device into the PCB ground planes. These multiple via grounds are also required to achieve the noted RF performance.

CONTROL PIN VOLTAGE & RESISTANCE VALUES

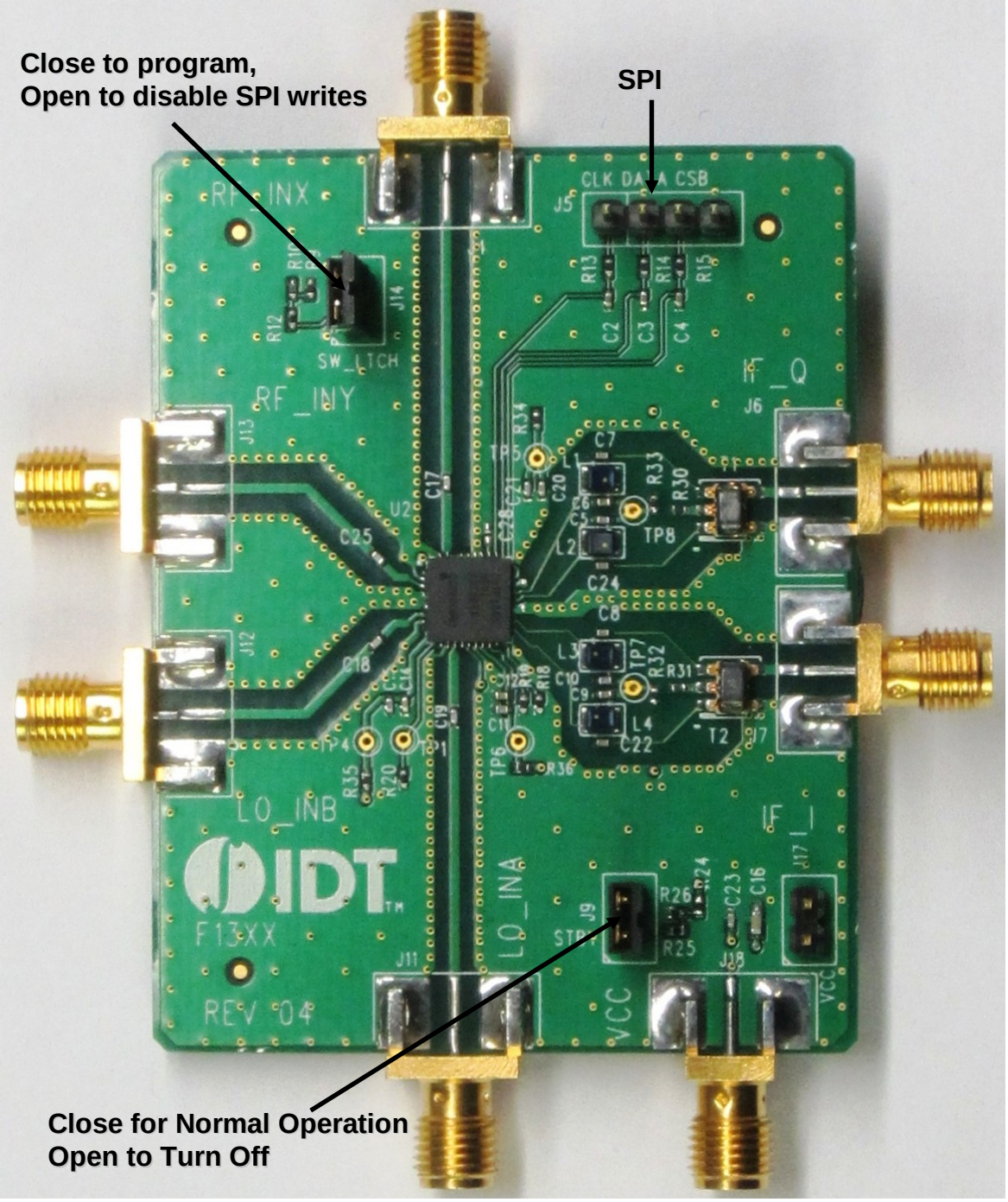
The following table provides open-circuit DC voltage and resistance values referenced to ground for each of the control pins listed.

Pin	Name	DC voltage (volts)	Resistance (ohms)
1	SW_LATCH	1.75	1.6M
14	STBY	5	50k
26	CSb	1.75	1.6M
27	DATA	1.75	1.6M
28	CLK	1.75	1.6M

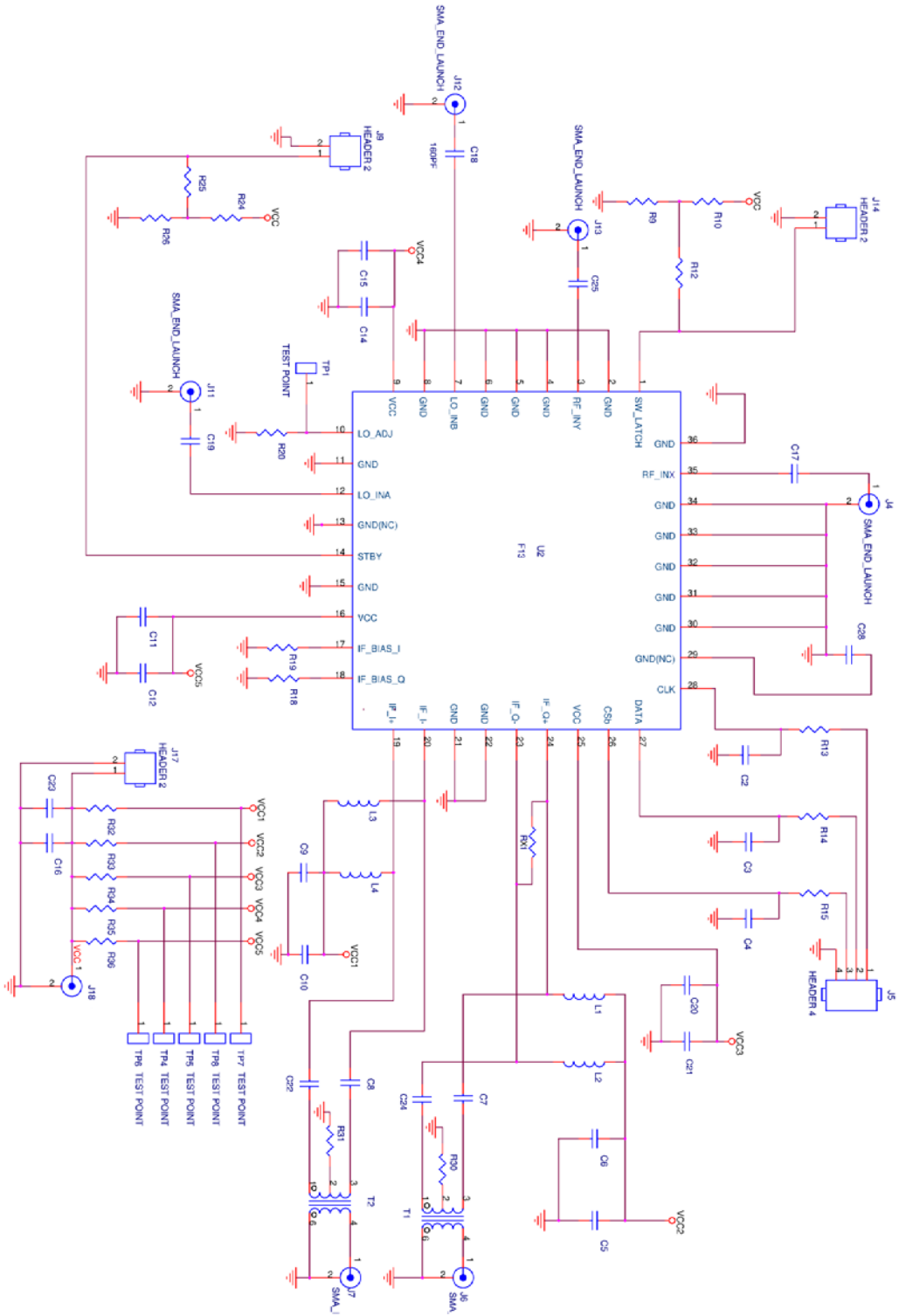
POWER SUPPLIES

All supply pins should be bypassed with external capacitors to minimize noise and fast transients. Supply noise can degrade noise figure and fast transients can trigger ESD clamps and cause them to fail. Supply voltage change or transients should have a slew rate smaller than 1V/20us. In addition, all control pins should remain at 0V (+/-0.3V) while the supply voltage ramps or while it returns to zero.

EVKIT PICTURE / LAYOUT / OPERATION



EVKIT / APPLICATIONS CIRCUIT



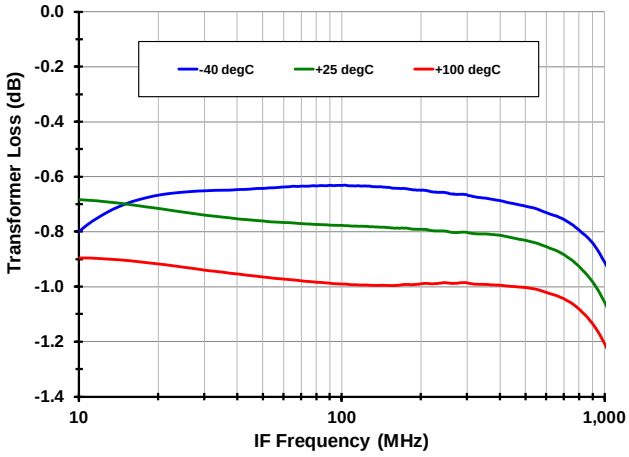
EVKIT BOM

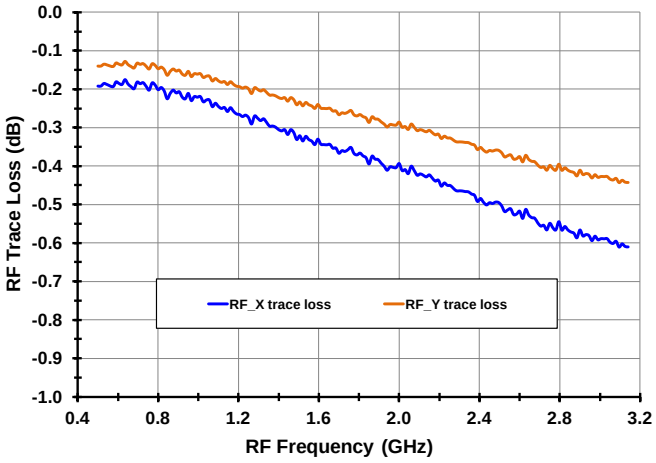
F1300 BOM
9/17/2013

Item #	Value	Size	Desc	Mfr. Part #	Mfr.	Supplier Part #	Supplier	Part Reference	Qty
1	100pF	0402	CAP CER 100PF 50V 5% NP0 0402	GRM1555C1H101JZ01D	MURATA	490-3458-1-ND	Digikey	C2-C4	3
2	10nF	0402	CAP CER 10000PF 16V 10% X7R 0402	GRM155R71C103KA01D	MURATA	490-1313-1-ND	Digikey	C6,7,8,9,12,14,21,22,24	9
3	1000pF	0402	CAP CER 1000PF 50V C0G 0402	GRM1555C1H102JA01D	MURATA	490-3244-1-ND	Digikey	C5,10,11,15,20,23	6
4	160pF	0402	CAP CER 160PF 50V 5% NP0 0402	GRM1555C1H161JA01D	MURATA	490-3230-1-ND	Digikey	C17,18,19,25	4
5	10uF	0603	CAP CER 10UF 6.3V X5R 0603	GRM188R60J106ME47D	MURATA	490-3896-1-ND	Digikey	C16	1
6	Header 2 Pin	TH 2	CONN HEADER VERT SGL 2POS GOLD	961102-6404-AR	3M	3M9447-ND	Digikey	J9,14,17	3
7	Header 4 Pin	TH 4	CONN HEADER VERT SGL 4POS GOLD	961104-6404-AR	3M	3M9449-ND	Digikey	J5	1
8	SMA_END_LAUNCH	.062	SMA_END_LAUNCH (Small)	142-0711-821	Emerson Johnson	530-142-0711-821	Mouser	J6,7,18	3
9	SMA_END_LAUNCH	.062	SMA_END_LAUNCH (Big)	142-0701-851	Emerson Johnson	530-142-0701-851	Mouser	J4,11,12,13	4
10	1uH	0805	0805LS (2012) Ceramic Chip Inductor	0805LS-102XJLB	COILCRAFT	0805LS-102XJLB	COILCRAFT	L1,2,3,4	4
11	43K	0402	RES 43K OHM 1/10W 1% 0402 SMD	ERJ-2RKF4302X	Panasonic	P43.0KLCT-ND	Digikey	R10,24	2
12	75K	0402	RES 75K OHM 1/10W 1% 0402 SMD	ERJ-2RKF7502X	Panasonic	P75.0KLCT-ND	Digikey	R9,26	2
13	2.8K	0402	RES 2.8K OHM 1/10W 1% 0402 SMD	ERJ-2RKF2801X	Panasonic	P2.80KLCT-ND	Digikey	R20 (Note 1)	1
	4.02K		RES 4.02K OHM 1/10W 1% 0402 SMD	ERJ-2RKF4021X		P4.02KLCT-ND		R20 (Note 2)	
14	121	0402	RES 121 OHM 1/10W 1% 0402 SMD	ERJ-2RKF1210X	Panasonic	P121LCT-ND	Digikey	R18,19	2
15	47K	0402	RES 47.0K OHM 1/16W 1% 0402 SMD	RC0402FR-0747KL	Yageo	311-47.0KLRCT-ND	Digikey	R12,25	2
16	100	0402	RES 100 OHM 1/10W 1% 0402 SMD	ERJ-2RKF1000X	Panasonic	P100LCT-ND	Digikey	R13-15	3
17	0	0402	RES 0.0 OHM 1/10W 0402 SMD	ERJ-2GE0R00X	Panasonic	P0.0JCT-ND	Digikey	R30,31,32,33,34,35,36	7
18	1:4 Balun	SM-22	SMT TRANSFORMER 10MHZ-1.9GHZ	RFXF6553-TR13	RFMD	689-1067-1-ND	Digikey	T1,2	2
19	F1300	QFN-36	DPD Demodulator	F1300	IDT	F1300	IDT	U1	1
20	PCB	05	Printed Cicuit Board	F13XX REV 05			SBC		1
21	BOM	02	Bill Of Material						
								Total	61

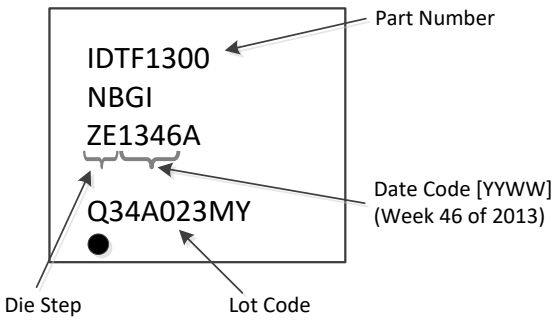
Note 1: Use this value for LO Freq Range 1 as specified in the Electrical Specification table in this datasheet
Note 2: Use this value for LO Freq Range 2 as specified in the Electrical Specification table in this datasheet

EVKIT LOSSES





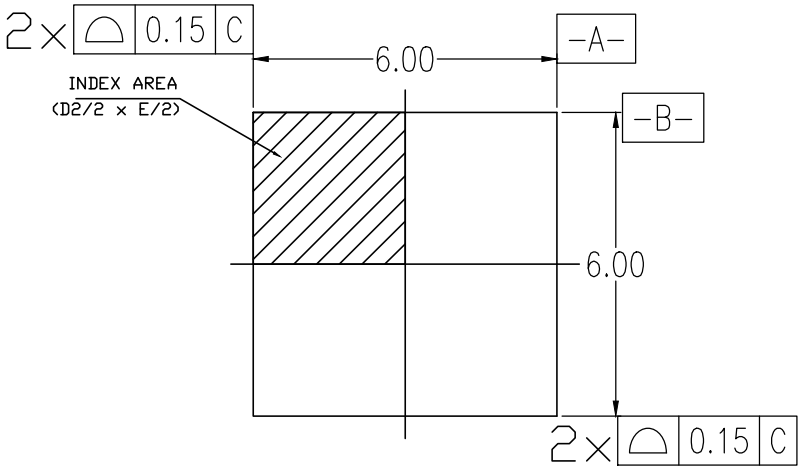
TOP MARKINGS



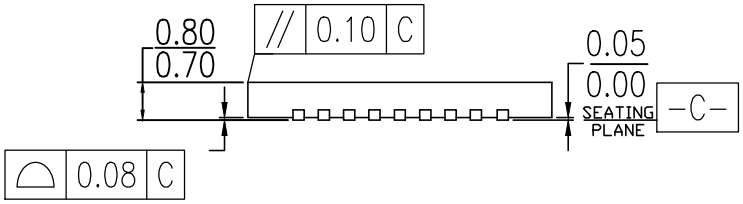
Revision Date	Description
February 7, 2022	Rebranded to Renesas.
May 5, 2014	Initial release.

36-VFQFPN, Package Outline Drawing

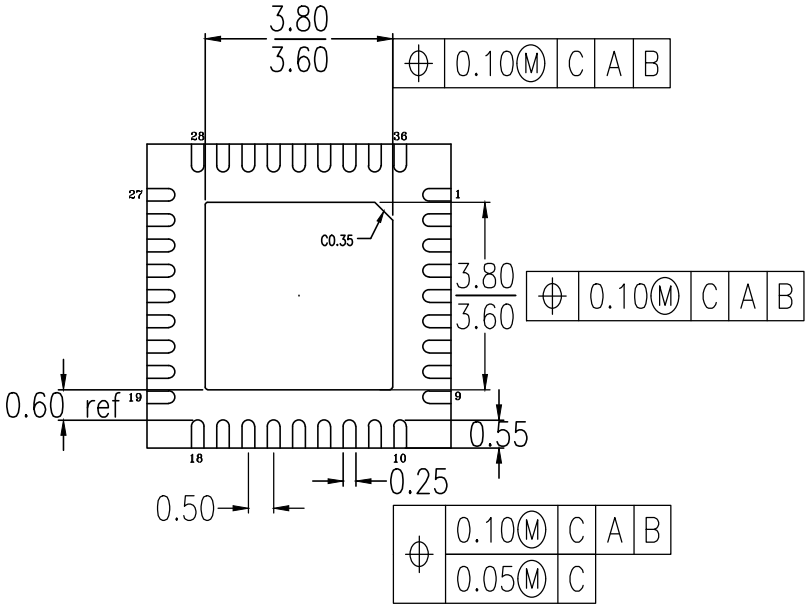
6.00 x 6.00 x 0.75 mm Body, 3.70 x 3.70 mm Epad, 0.5mm Pitch



TOP VIEW



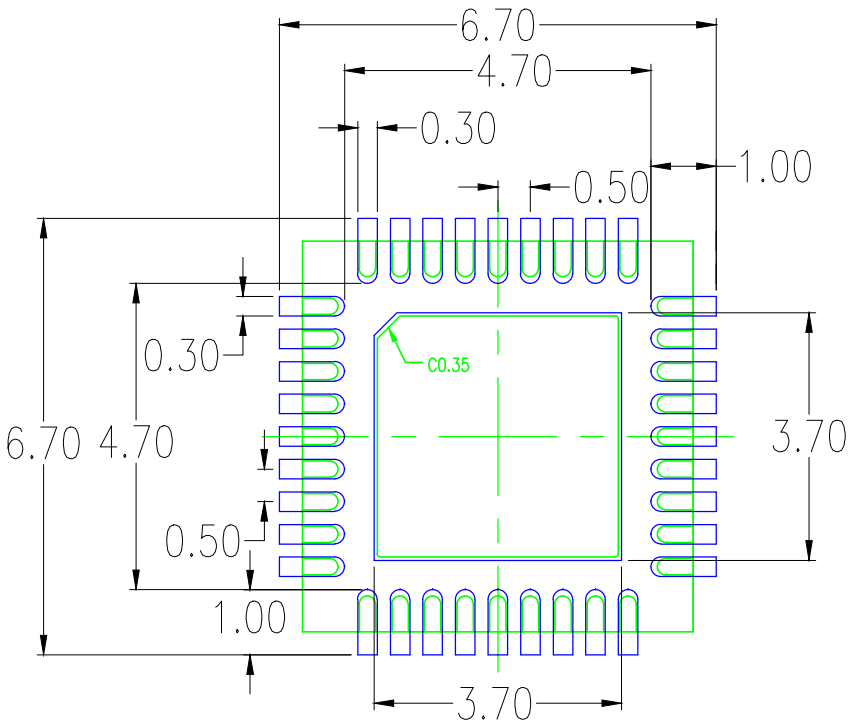
SIDE VIEW



BOTTOM VIEW

NOTES:

1. ALL DIMENSIONING AND TOLERANCING CONFORM TO ANSI Y14.5M–1982
2. ALL DIMENSIONS ARE IN MILLIMETERS.



RECOMMENDED LAND PATTERN DIMENSION

NOTES:

1. ALL DIMENSION ARE IN mm. ANGLES IN DEGREES.
2. TOP DOWN VIEW. AS VIEWED ON PCB.
3. COMPONENT OUTLINE SHOW FOR REFERENCE IN GREEN.
4. LAND PATTERN IN BLUE. NSMD PATTERN ASSUMED.
5. LAND PATTERN RECOMMENDATION PER IPC-7351B GENERIC REQUIREMENT FOR SURFACE MOUNT DESIGN AND LAND PATTERN.

Package Revision History		
Date Created	Rev No.	Description
Nov 8, 2021	01	Update IDT format to Renesas format
Apr 6, 2016	00	Initial Release